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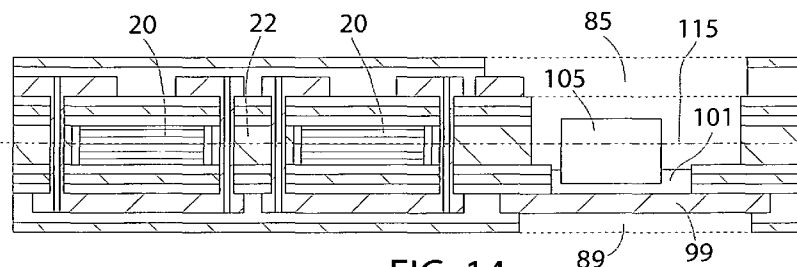


FIG. 14

(57) Abstract: An embedded device (105) is assembled within a flexible circuit assembly (30) with the embedded device mid-plane intentionally located in proximity to the flexible circuit assembly central plane (115) to minimize stress effects on the embedded device. The opening (18), for the embedded device, is enlarged in an intermediate layer (10) to enhance flexibility of the flexible circuit assembly.

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FLEXIBLE CIRCUIT ASSEMBLY AND METHOD THEREOF

The following patent application is related to and claims priority from United States provisional patent application number US 61/497,472 filed June 15, 2011.
5 The following patent application is related to United States Non-Provisional Patent Application US 13/506,110.

10 TECHNICAL FIELD OF THE INVENTION

The present invention relates generally to flex circuits and rigid flex circuits, and more particularly to the embedding of devices into flex circuits and rigid flex circuits.

15

BACKGROUND OF THE INVENTION

Flex and rigid flex circuits are used extensively in applications, including automotive, computers and peripherals, small consumer devices, medical
20 electronics, telecommunications, military, and aerospace, where space utilization and weight are a premium.

Flex circuitry incorporates metal lines sandwiched between non-conductive flexible layers to save space in routing of metal interconnect lines. However, as
25 more layers of metal and non-conductive substrates are added to the sandwich, the flex circuit becomes less flexible. Attempts to add electrical or electronic devices require the mounting of components onto the surfaces of a flex sandwich. The surface mounted components, i.e., surface mounted devices (SMDs), make the flex circuit even more rigid and less flexible.

30 Electronic systems are often separated onto two or three circuit boards. Rigid printed circuit boards (PCBs) are used to mount and support the electronic devices and include many copper layers to interconnect the respective SMDs.

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Separate flexible interconnects are used to provide interconnection between the rigid PCBs. Flexible circuits are typically structured with two or more metal layers. Thus, the system is somewhat flexible in the interconnect flex circuit regions, but rigid where components are mounted. Therefore, the multi-component system is not optimized for size and weight parameters.

Furthermore, the combined PCB – flex manufacturing processes are complex. Rigid flex technology employs methods to thicken and stiffen a region of the flexible circuit to provide a region that is mechanically rigid to accommodate fragile components, e.g., surface mount devices and through hole connectors.

The process for inclusion of SMDs is likewise complex and less cost effective. For example, over-molding of devices such as semiconductor circuits, require additional assembly and packaging process steps. A component device, e.g., a light emitting diode (LED), likewise is diced from a wafer, assembled into a packaged device, and the packaged device is then mounted to a PCB to complete assembly.

In addition, the aforementioned PCB substrates are poor conductors of heat. Therefore, when heat generated by the mounted device is excessive, e.g., in the case of LEDs, power circuits, microprocessors, etc., more expensive thermally conductive substrates accompanied with the attachment of a bulky conducting heat sink are required. The heat sink is attached to the underside of metal core substrate, PCB, or on top of the packaged SMD to transfer the heat away from the mounted device. The heat sink is typically metallic copper or aluminum and its attachment to the substrate or package make the assembly bulky, heavy, and inflexible.

Therefore, what is needed is an ultra flexible flex process technology that permits mounting of an increased number of devices in a cost effective weight and space saving manner, transfers heat efficiently away from heat generating devices, and incorporates highly effectual automated roll-to-roll manufacturing concepts.

BRIEF DESCRIPTION OF THE DRAWINGS

FIG. 1 illustrates a top view of the present invention.

5 **FIG. 1a** illustrates a top view of the present invention illustrating specific areas of interest for **FIGs. 6-15**.

FIG. 2 illustrates a top view of a portion of **FIG. 1** and further illustrates a cross-section relating to **FIGs. 6-15**.

10 **FIG. 3** illustrates a bottom view of a portion of **FIG. 1** and further illustrates a cross-section relating to **FIGs. 6-15**.

FIG. 4 illustrates top view of the cut and patterned intermediate layer of the present invention

FIG. 5 illustrates a partial and expanded top view of the present invention showing the patterned intermediate layer.

15 **FIG. 6** illustrates a cross-sectional view of the present invention showing the attachment configuration of the intermediate layer and a copper layer assembly.

FIG. 7 illustrates a cross-sectional view of the present invention showing an embedded magnetic core and embedded island configuration.

20 **FIG. 8** illustrates a cross-sectional view of the present invention showing a cut copper lamination assembly attachment to the intermediate layer assembly

FIG. 9 illustrates a cross-sectional view of the present invention showing via openings.

FIG. 10 illustrates a cross-sectional view of the present invention showing via openings after plating process.

25 **FIG. 11** illustrates a cross-sectional view of the present invention showing patterned and etched copper layers.

FIG. 12 illustrates a cross-sectional view of the present invention showing cuts and lamination of cover layers.

30 **FIG. 13** illustrates a cross-sectional view of the present invention showing detail after laser skiving of the LED opening and after the electroplating process.

FIG. 14 illustrates a cross-sectional view of the present invention showing chip (die) attach.

FIG. 15 illustrates a cross-sectional view of the present invention showing chip (die) wire bond, encapsulation, and inductor loop path.

FIG. 16 illustrates a top view of the present invention showing further detail of the LED openings for the completed flexible assembly.

5 **FIG. 17** illustrates a bottom view of the present invention of **FIG. 16**.

FIG. 18 illustrates a circuit diagram of the present invention showing an AC LED implementation.

FIG. 19 illustrates a circuit diagram of the present invention showing an alternative AC LED implementation.

10 **FIG. 20** illustrates a top view of the present invention showing laminated magnetic core elements.

FIG. 20a illustrates an exploded view of the present invention showing a ferrite core structure.

15 **FIG. 21** illustrates a top view of the present invention showing detail after cutting of the flexible strip assembly to enhance flexibility of the flexible assembly.

FIG. 22 illustrates an implementation of the present invention applicable to configurable lighting.

SUMMARY OF THE INVENTION

Electronic circuit applications continually require technologies that minimize
5 product size, weight, and cost. Form factors continually shrink, requiring flexibility
in arranging and mounting components. Likewise, as form and size constraints
are applied, heat generated by electronic and electric devices is also constrained
to smaller areas and places a further burden on effectively dissipating heat from
the restricted areas.

10 The present invention describes a method for fabricating a cost effective
ultra flexible circuit assembly that accommodates efficient reduced stress, with
reduced space requirements and enhanced heat transfer.

Present technology uses a combination of flex and rigid flex technology in
an attempt to achieve the desired results. However, present technology requires
15 tradeoffs and falls short of the desired goals.

In the inventive process, circuit flexibility of an assembly is enhanced by
removing material from a non-conductive intermediate layer, from conductive
layers, and from other non-conductive layers in the flexible circuit assembly.
Additional material is removed from the intermediate and other layers, to facilitate
20 openings through which components are attached (embedded) and to further
enhance flexibility within the highly flexible substrate.

The intermediate layer of non-conductive material and other layers are
patterned with a number of openings. The openings define areas for component
mounting, areas for enhanced flexibility, and areas for stress relief. The openings
25 also function to define target areas for "pick and place" type manufacturing
operations. The non-conductive intermediate layer is attached with adhesive to a
thin and highly flexible layer of material, e.g., copper on polyimide. Electronic
components, electronic devices, and passive devices are then affixed to the highly
flexible material, and embedded in the intermediate layer openings.

30 Interconnecting top and bottom conductive layers are affixed and patterned as
required to complete circuit connections. Interconnect from and to the embedded
devices is implemented through utilization of wire bonding, tape automated

bonding (TAB), and / or solder attachment. The completed assembly is covered with protective coatings.

Accordingly, it is the object of the present invention to provide a method for fabricating an assembly of electronic and electric devices, along with
5 corresponding interconnects, that exhibits highly flexible characteristics.

It is another object of the present invention to embed electronic and electrical devices and components, both active and passive, in the flexible assembly in a cost effective manner.

It is still another object of the invention to minimize the number of processes
10 and the amount of raw materials required to complete the flexible assembly.

It is a further object of the invention to produce a flexible assembly of electronic and electric devices that exhibits enhanced heat dissipation characteristics.

It is yet a further object of the invention to produce a flexible assembly of
15 electronic and electric devices that exhibits reduced stress characteristics.

It is still a further object of the invention to produce a highly flexible electronic and electrical device assembly that exhibits reduced weight characteristics.

It is more so an object of the invention to produce a highly flexible electronic
20 and electrical device assembly that is completely compatible with automated techniques.

It is an additional object of the present invention to provide an inductor structure that exhibits a magnetic field parallel to the plane of the flexible assembly.

It is yet an additional object of the present invention to provide an inductor
25 with a laminated core that exhibits reduced stress characteristics.

It is still yet an additional object of the present invention to provide an inductor and other electronic and electrical devices with three dimensional characteristics.

It is moreover an object of the present invention to provide a method of
30 fabrication, within a flexible circuit assembly, that eliminates the need for

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packaging electronic and electrical devices prior to assembly of the flexible circuit assembly.

It is moreover another object of the present invention to fabricate mechanically stable, thin, laminated magnetic cores having narrow air gaps.

5 It is moreover still another object of the present invention to provide a completely integrated functioning LED lighting system with all necessary components all embedded within the same flexible circuit assembly.

It is even moreover another object of the present invention to provide a completely integrated functioning LED lighting system that is powered directly from
10 an alternating current (AC) source.

DETAILED DESCRIPTION OF THE DRAWINGS

The present invention is a highly flexible circuit assembly suitable for use in
5 a number of constrained form factor and limited space applications and ideally
adapted for automated manufacturing techniques.

Referring to **FIG. 1**, a top view of a flexible circuit assembly of the present
invention is shown. Flexible circuit assembly **30** is configured with Inductor area
10 **130**, LED area **135**, and surface metallization interconnect **35**. LED area **135**, for
example, is an array of embedded circuits that is 6 wide by 7 deep. LED area **140**
is contained within LED area **135**. Further detail is omitted from **FIG. 1** to provide
a more simplified view of the flexible circuit assembly concept.

Referring to **FIG. 1a**, the flexible circuit of **FIG. 1** is shown enlarged and
15 severed at break line **25** to provide more clarity as to the structure of the flexible
circuit. Patterned metallization layer **35** includes diode metallization, inductor
metallization, and interconnect metallization (all not annotated). The patterned
metallization serves as a reference, for purpose of discussion, for location of
internal cut lines **212** and **215**, peripheral cut lines **214**, and drill openings **218**.
20 The internal cut lines facilitate extension of flexible circuit assembly **30** into an ultra
flexible circuit assembly of **FIG. 21** and **FIG. 22**.

Referring to **FIG. 2**, a portion of flexible circuit assembly **30** of **FIG. 1**, i.e.,
inductor area **130** and LED area **140**, is expanded to provide more detail for cross-
section **120**. The cross-section intersects vias **51**, **53**, **57**, **59**, inductor winding
25 metallizations **37**, **39**, **67**, and **69**, i.e., top windings, and LED chip (die) **105**, to
provide basis for cross-sectional views for **FIGs. 6** through **15**.

Referring to **FIG. 3**, i.e., an under view of expanded **FIG. 2**, cross-section
120 intersects vias **51**, **53**, **57**, **59**, inductor winding metallizations **54** and **58**, i.e.,
bottom windings, and LED chip **105** (not shown).

30 Looking to **FIG. 4**, intermediate layer **10** layout includes inductor opening
15, LED extended opening **18**, LED openings **16**, extended flex LED opening **19**,
and extended flex openings **216**. Peripheral cut lines **214** and internal cut lines

212 and **215** are not defined within the intermediate layer, but are illustrated for purpose of reference location to the aforementioned openings. The cut lines are defined using a CAD tool and router cut following completion of assembly steps for flexible circuit assembly **30**, resulting in the ultra flexible structure of **FIG. 21**.

5 Looking now at **FIG. 5**, an expanded portion of intermediate layer **10** of **FIG. 4** is shown

 In **FIG. 5**, inductor opening **15** and LED opening **18** are configured within intermediate layer **10**. The openings are pre-defined, e.g., using a CAD layout tool. Chip (die) target area **17** is predetermined to optimize placement of an LED
10 chip (die) within the LED opening. For this example, due to the inflexible nature of a semiconductor LED chip, spaces between the intermediate layer walls and the LED chip are selected to be minimized on three sides to provide additional support and to reduce stress to the more rigid chip. The spaces, for this example are 0.13mm. For the fourth side of the chip target, LED opening **18** is enlarged to
15 provide an area of greater flexibility for flexible circuit assembly **30**. Likewise, LED opening **16** is enlarged to facilitate its respective LED chip.

 The configured openings are then cut, in intermediate layer **10** using a routing tool computer controlled by the CAD data file that was used to generate the intermediate layer pattern. Inductor opening **15** and LED openings **16** and **18**
20 provide access for mounting of inductor and LED components, respectively, within the flexible circuit assembly. The openings may also serve as assembly alignment targets for automated assembly processes. One skilled in the art realizes that other methods are available to cut non-conductive and conductive layers. Other cutting methods are, but are not limited, to laser, knife blade, and stamping.

25 For this example, the openings are configured to be inductor and LED specific. However, one skilled in the art would recognize that other electrical, electronic, optical, mechanical, electro-mechanical, and electro-optical devices may be facilitated by the process.

 The intermediate layer is, but is not limited to polyimide. Alternative
30 dielectric type materials used for the intermediate layer, and for other non-conductive layers, are, but are not limited to, polyester-imide, aramid paper, mylar,

polyethylene, polyvinylchloride, fiber reinforced epoxy, Teflon® FEP, and sandwiched layers of copper/flex circuits.

Referring to **FIG. 6**, processing of flexible circuit structure **30** continues. Intermediate layer **10** is patterned and processed as described in the description for **FIG. 5**. A one-sided 0.025 mm thick dielectric film **12**, having a 2 ounce copper layer **14** is first attached to the underside of intermediate layer **10** via adhesive layer **11**. For this example, a thick one-sided dielectric film assembly is selected with adhesive layer **13** inherently present between thick dielectric film **12** and 2 ounce copper layer **14**. Thus, the combination of copper layer **14**, adhesive layer **13**, thick dielectric film **12**, and adhesive layer **11** forms film assembly structure **46**.

Alternatively, the film assembly may be selected without the adhesive layer **13**. This type of starting film assembly has copper layer **14** directly bonded to dielectric film **12**. The resulting film assembly is thinner and therefore more flexible in nature.

For this example, the thickness of intermediate layer **10** is 0.127 mm with a typical range of 0.01 mm to 1.0 mm. Adhesive layers **11** and **13** are 0.051 mm and 0.025 mm respectively.

As one skilled in the art would recognize, thicknesses of copper, dielectric and adhesive vary with specific processes and with physical device characteristics and are not limited to above thicknesses. Conductive layers are, but are not limited to rolled copper and include such variations as conductive organic film, printed / sintered copper, sputtered on copper, electroplated copper, aluminum and steel.

Looking now to **FIG. 7**, a pick and place equipment positions magnetic core **20** within inductor opening **15**, and positions and centers island **22** within the magnetic core. Pressure and heat are applied over the magnetic core and island assembly to affix the inductor components to adhesive layer **11**. The magnetic core and island are approximately of the same thickness as the intermediate layer to provide a planar surface for further processing of, e.g., interconnect layers. Island **22** is preferably the same material and same thickness as intermediate layer **10**.

One skilled in the art can appreciate that both intermediate layer **10** and island **22** closely match the thickness of magnetic core **20** which, for example, can range from 0.02 mm thick for a single layer magnetic core to a thickness of over 1.0 mm for a stacked laminated core. A thicker core provides capability for handling more electrical power, but results in decreased flexibility and adds weight to the flexible assembly.

Referring now to **FIG. 8**, copper layer **34** is affixed to one-sided dielectric film **32**, via adhesive layer **33** that is inherent to the one-sided dielectric film, and adhesive layer **31** to form structure **45**. One skilled in the art would ascertain that various combinations of metal adhesive and non-conductive films are available to configure stack **45**.

The stack is router cut, in a process similar to that of the intermediate layer, using the appropriate CAD data file to drive the router cutting tool. The referenced router cut presents opening **86** in the stack to provide access to LED opening **18**, the openings are concurrently placed to facilitate embedding of the LED chip (die).

For this example, one-sided dielectric layer **32** is 0.025 mm thick, having a 2 ounce copper layer **34**. Adhesive layers **31** and **33** are 0.051 mm 0.025 mm, respectively.

Thicknesses of copper, dielectric and adhesive may vary to accommodate characteristics and requirements of specific processes and are not limited to references cited in the preceding example. Conductive layers are, but are not limited to rolled copper and include such variations as conductive organic film, printed / sintered copper, sputtered on copper, electroplated copper and aluminum.

A lamination process is used to affix structure **45** to the flexible circuit structure of **Fig. 7**.

The lamination process utilizes a mechanically pressurized baking step to cure adhesive layers **11**, **13**, **31** and **33**. Pressurized cure under atmosphere or vacuum, plus bake methods used for this process, are known to those skilled in the art.

As a result of the lamination process, magnetic core **20** and island **22** are now sandwiched between dielectric film **32** and dielectric film **12**. Core space **36**,

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between intermediate layer **10** and magnetic core **20**; and island space, **38** between magnetic core **20** and island **22**, will be at least partially, if not completely filled in by the adhesive layers **11** and **31** squeezing into both spaces. The degree of filling is dictated by material dimensions and by lamination process parameters, e.g., pressure and heat.

As one skilled in the art would recognize, the provided LED opening **18**, for this example, does not imply a limitation only to the assembly of LEDs in combination with inductors, and alternatively may be used for assembly of device types other than LEDs and inductors.

Referring now to **FIG. 9**, via openings **41**, **43**, **47**, and **49** are configured by a drilling process that is controlled by data from a CAD file. The vias, for this example, provide access to copper layer **14** and to copper layer **34** to facilitate interconnect of the inductor windings shown in **FIG. 1**.

Referring now to **FIG. 10**, via openings **41**, **43**, **47**, and **49** are plated to form plated vias **51**, **53**, **55**, and **57**. The plated vias serve as a vehicle for interconnecting metallization patterns within the flexible circuit assembly. For this example, the plated vias couple the windings of the embedded inductor.

Cleaning and / or activation steps common to flex manufacturing for via plating are known to those skilled in the art and are not described here. Copper plating of via openings is, but is not limited to an electro-less process, an electrolytic process, or a combination of both.

Looking now to **FIG. 11**, copper layer **34** and copper layer **14**, of **FIG. 10**, are configured with patterns defined by two dry film masks, respectively. A photosensitive film is applied to copper layer **34**. The respective mask is aligned to the via layer. The photosensitive film is exposed to UV light, through metal layer predetermined defined openings in the mask. The dry film is then chemically developed to form the desired patterns.

Likewise, a photosensitive film is applied to copper layer **14**, of **FIG. 10**. The respective mask is aligned to the via layer. The photosensitive film is exposed to UV light, through the metal layer defined openings in the mask. The dry film is then chemically developed to form the predetermined etch patterns.

Next the dry film masked metallizations are immersed to chemically etch both copper layers **34** and **14**. After etching of the copper layers, the dry film masks are removed. The resulting metallization patterns are inductor winding metallizations **37**, **39**, and **54**; inductor winding metallizations **67**, **69**, and **58**; and wire bond copper pad **95**. The inductor metallization patterns are also shown in **FIGs. 1** through **3**.

Referring now to **FIG. 12**, coverlay layer **82**, with attached adhesive layer **71**, is router cut to create opening **85** and then attached to the assembly of **FIG. 11**. For this example, the coverlay layer is 0.025 mm thick polyimide, and the adhesive layer is 0.05 mm. Alternatively, other dielectric materials, e.g., solder mask and/or adhesives known to those skilled in the art may be used for the coverlay. Pressure, or alternatively pressure and heat, is used to affix the coverlay structure to the assembly of **FIG. 11**.

Likewise, coverlay layer **84**, with attached adhesive layer **73**, is router cut and affixed to the assembly of **FIG. 11** using adhesive layer **73**. The coverlay layer is 0.025 mm thick polyimide, and the adhesive layer is 0.05 mm.

The coverlay serves to insulate and to protect the underlying metallization patterns from exposure to external environments and also a target for exposing areas for further processing. In **FIG. 12**, coverlay layer **82** is configured to expose copper pad **95** and LED opening **18** and expanded LED opening **85**. Coverlay layer **84** performs the corresponding function for underlying metallization and for coverlay opening **89** for exposure to copper flag **99**.

Coverlays are cut using a computer controlled router. A CAD file is configured to drive the router to remove the respective coverlay polyimide and adhesive material to form the openings **85** and **89**.

Referring now to **FIG. 13**, embedding heat generating devices, such as LED **105**, within flexible circuit assemblies, requires an effective method for transferring the heat from the device, in order to maintain a thermal gradient that will not cause damage to the device. Additionally, it is beneficial to reduce mechanical stresses seen by embedded devices to accommodate a higher degree of flexibility within the assembly. In **FIG. 13**, an optimal solution is provided for embedded component heat transfer and stress reduction for flexible circuit assembly **10**.

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A predetermined area of adhesive **11**, dielectric film **12**, and adhesive **13** of **FIG. 12**, is removed by a laser skiving process, thus providing a device placement opening. The removal of skive area opening **88** is accomplished, for example, by a laser cutting tool. The tool is computer driven from a CAD data file, programmed
5 for the predetermined skive area. The laser power level is set to remove organic films while leaving copper materials intact.

The layers are removed, exposing copper flag **99** in skive area opening **88**. The copper flag serves as laser etch stop during the laser skiving process and seals the bottom side of the LED opening. The total chip (die) opening of LED
10 opening **18**, coverlay opening **85**, and skive area opening **88**, is designed to provide easy access, to the now exposed copper flag, for placement of the embedded device.

Additionally for this example, copper chip (die) bond pad **95** and copper flag **99** are pre-cleaned, followed by plating of nickel and gold onto the exposed copper
15 surfaces. Plating on the exposed copper promotes wire bond quality and corrosion resistance. One skilled in the art realizes the plated copper surface may also be configured for tape automated bonding (TAB). Plating compositions are, for example, but not limited to NiPdAu, NiPd, Au and CrAu. Alternatively, copper surfaces may remain unplated, for solder attachment applications.

Looking now to **FIG. 14**, thermally conductive epoxy adhesive **101** is
20 dispensed into skive area opening **88** and onto copper flag **99**. For this example, LED chip (die) **105** contacts, e.g., gold, are both on the upper chip (die) surface, thus negating the need for a backside electrical chip (die) contact. The adhesive is, but is not limited to for example, diamond filled epoxy, and other compositions
25 containing filler materials of either silver flakes, alumina, particles, or nano-fibers.

Alternatively, should a backside electrical chip (die) contact be required, an electrically conductive epoxy may be used, or tape automated bonding or solder die attach may be employed.

Copper flag **99** may be configured as an interface to other electrical
30 components within the flexible circuit assembly. Additionally, a heat sink medium can also be affixed to the copper flag through coverlay opening **89** to accommodate more rapid heat transfer as required by an embedded device.

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LED chip (die) **105** is accurately placed inside LED opening and over the epoxy adhesive using an automated die (chip) pick and place equipment. The completed assembly is next subjected to a heat, or alternatively an ultraviolet (UV) cure cycle to firmly attach the LED chip (die) to the copper flag.

5 Looking further to **FIG. 14**, central plane **115** intersects the embedded structures, i.e., LED chip (die) **105**, inductor magnetic core **20**, and island **22**. The central plane is a plane of least stress for the flexible circuit assembly. Mechanical stresses are reduced greatly by placing the embedded devices adjacent to or intersecting the central plane, i.e., in proximity to the central plane. Alternatively,
10 for example, a mid-plane (not shown) is defined as a plane that lies between the top surface and bottom surface of the device, and approximately bisects the embedded device. The placement of the mid-plane in proximity to central plane **115** minimizes the mechanical stress on the embedded device.

 The central plane is a plane of zero stress when flexible circuit assembly **30**
15 is subjected to bending. For this example, where layers located above the central plane are equivalent in number, thickness, structure, and composition to layers located below the central plane, i.e., symmetrical, the central plane is physically located at the center of the aforementioned layers.

 Where layers of the flexible circuit are not symmetrical, e.g., different in
20 numbers, thicknesses, structure, or composition, a computer generated stress analysis program is used to determine the location of the central plane. Correspondingly, the flexible circuit is designed to embed components and devices to intersect, or to be located in proximity to (adjacent to) the central plane, in a predetermined manner, therefore minimizing stress effects within the flexible
25 circuit.

 Looking now to **FIG. 15** gold wire **110** is ball bonded to LED chip (die) **105**, and wedge bonded to copper bond pad **95** to complete the bonded chip (die) assembly. Following the bonding process, the bonded chip (die) assembly is encapsulated using, for example, optically transparent encapsulant **111**. The
30 encapsulant is dispensed on the LED chip (die), the wire bonds, and copper bond pad to protect the assembly. The encapsulant also aids in guiding radiated light

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from the LED chip (die). Florescent powder maybe added on surface of the LED chip (die) or mixed into the encapsulant to alter visible color of radiated light.

The encapsulant, for this example, is a silicone based gel, but alternatively is, but is not limited to, grease and over-molding compounds, both silicone based and non-silicone based. In certain applications, phosphor particles embedded
5 within the encapsulant are used to convert blue or UV LED light to yellow, green and red light

Again looking to **FIG. 15**, and in conjunction with **FIG. 2** and **FIG. 3**, the three dimensional aspect of inductor wire loops **160** and **162** becomes evident.
10 The inductor loops are wound in a three dimensional pattern, including inductor wire metallizations **37**, **54**, **39**, **67**, **58**, and **69**, to form the inductor loops. Furthermore, the resulting inductor loops generate lateral magnetic fields parallel to central plane **115** of the flexible circuit assembly and are therefore confined mostly within the magnetic core, thus reducing the effect of the stray field lines on
15 components and metallization patterns located on adjacent or near adjacent layers of the assembly. This is particular importance in reducing the impact of stray electromagnetic interference (EMI) effects when considering a flexible circuit assembly with multilayer metal configurations and sensitive electronic components.

20 Incorporating the processes of **FIGs. 6** through **15**, the flexible circuit assembly of **FIG. 1**, results in a singulated flexible circuit assembly of dimensions 78 mm wide x 183 mm long x 0.8 mm thick. The measured weight of the singulated assembly, including LEDs, encapsulant, and inductor with steel core, is 9 grams.

25 The inductor of **FIG. 1**, is 15mm wide x 40.3 long x 0.11mm thick, with a core opening of 2.8mm x 28.1mm. The inductor exhibits an inductance value of approximately 350 micro Henries, measured at 60 hertz.

As one skilled in the art would recognize, the concepts represented above in **FIGs. 6** through **15**, although referenced to inductors, can equally be applied to
30 transformer circuit elements, and do not deter from the spirit of the invention.

Referring to **FIG. 16**, a portion of the completed flexible circuit assembly is shown. LED opening **16** lies adjacent to LED openings **18**, and like LED openings

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18, is similarly elongated to facilitate enhanced flexibility of flexible circuit assembly 30 of FIG. 1 and to provide stress relief for embedded components. LED chip (die) 105, 163, and 167 are placed in the respective openings in close proximity to three sides of the openings to provide mechanical support for the respective LED chip (die). Coverlay opening 85 exposes the respective LED openings to facilitate ease of LED device assembly and to enhance flexibility within the flexible circuit assembly.

For simplicity, only the wire bond detail for LED chip (die) 105 is shown in FIG. 16. For this example, LED chip (die) are configured with both anode and cathode connections on the same surface of the chip (die). The anode of LED chip (die) 105 is coupled to wire bond pad 95 through bond wire 110. The cathode of the LED chip (die) is coupled to wire bond pad 142 through bond wire 141. Alternatively, the LED chip (die) anode and cathode can be disposed on opposite sides of the chip (die), wherein one connection is wire bonded to a wire bond pad and the second connection is made to a copper flag of the flexible circuit assembly, such as copper flag 99 of FIG. 17. Additionally, anode and cathode connections can be made using thermal bumps on the LED chip (die). The LED chip (die) is then TAB or flip-chip bonded to segmented copper flags (not shown) in the flexible circuit assembly.

20

Referring to FIG. 17, a bottom view of FIG. 16 is shown. LED chip (die) 105, 163, and 167 are mounted to copper flags 99, 991, and 993, respectively, as described in the process for FIG.s 6 through 15. The copper flags are patterned in an enlarged configuration to facilitate enhanced thermal transfer away from the LED chips (dies). Coverlay openings 89, 992, and 994, provide access to the copper flags, for example, to permit air flow for cooling or for attachment of heat sinks to improve thermal transfer characteristics of the LED chip (die).

Referring to FIG. 18, an application of the present flexible circuit assembly invention is shown, incorporating 60 Hertz AC power source 170 to directly drive an LED lighting configuration. The AC power source is connected to LED string 179, through fuse 172, and transformer 174. The transformer is fabricated as an

30

embedded device, utilizing the flexible circuit assembly process described in FIG.s 6 through 15. As one skilled in the art would recognize, a transformer is an assembly of interspersed inductor windings. Thus, the inductors of the present invention are used to fabricate the embedded transformer.

5 LED string 179 is fabricated from serially connected back to front LED pairs 176. The secondary of transformer 174 is coupled to the LED string, at one end, through current limiting resistor 178, to the second end of the LED string.

Typically, for a 60 Hertz AC power source, powering an LED produces noticeable flicker. By incorporating the LEDs in a back to back configuration, the
10 LEDs operate in an efficient manner when AC current flows in either direction. Thus, the circuit operates in a mode equivalent to 120 Hertz, reducing noticeable flicker.

Referring to FIG. 19, another application of the present invention is shown, incorporating 60 Hertz AC power source 190 to directly drive an LED lighting
15 configuration. The AC power source is coupled to LED string assembly 196, through fuse 192, and transformer 194. The transformer is fabricated as an embedded device, utilizing the flexible circuit assembly process described in FIG.s 6 through 15.

LED string 196 is fabricated from diode 197 and LED string 199. Diode
20 197 provides greater reliability under reverse bias than a standard type light emitting diode. The secondary of transformer 194 is coupled to the LED string assembly, at one end, through current limiting resistor 198, and to the second end of the LED string assembly. The resultant configuration produces an equivalent 120 Hertz effect, thus reducing flicker in the LED lighting application.

25 Referring to FIG. 20, magnetic core layer 180, having air gap 181, and magnetic core layer 182, having air gap 183 are configured for stacking and lamination, utilizing the embedded concepts of FIG.s 6 through 15.

Air gaps are known in the art as desirable for reducing DC bias saturation in magnetic core stacks in inductors and transformers. As known in the art, air gaps
30 are stacked coincidentally. However, coincident stacking of air gaps in flexible circuits results in a potentially less stable mechanical structure that is subject to bending and damaging during the manufacturing process.

In **FIG. 20**, prior to assembly of the magnetic core, air gaps **181** and **183** are laser cut in an offset manner and on opposing sides of the respective magnetic core layers. The resulting laminated stack is thus configured with staggered air gaps located on opposite sides of the respective magnetic core layers. Thus, the adjacent magnetic core layers provide support in the area the of air gaps in the respective adjacent core layers while maintaining the desired impact of the air gap. The resulting laminated core is more stable than a laminated core with coincident air gaps.

Alternatively, the air gaps may be offset in a non-opposing manner, e.g., in quadrature or sequential, and also etched and / or filled with an insulating material.

The magnetic core is formed, for example, by gluing two sheets of steel to form a solid laminate of 0.13 mm thick. This laminate is masked on both sides, patterned and then chemically etched from both sides, using processes known to one skilled in art. The etching of the laminated steel cores result in a structure with an outer dimension of 15 x 40 mm and an inner dimension of 2.9 x 28 mm. Air gaps **181** and **183** are also formed in the etching process to a predetermined width of 0.06 mm.

Due to the offset of the air gaps, the resulting steel core can be handled and bent without altering the gap widths.

One skilled in the art would also recognize that more than two layers of metals can be processed to produce enhanced inductance characteristics. For example, with four copper layers, twice the number of windings is formed around the magnetic core thus creating larger inductances and more powerful transformers.

Inductors used in a frequency range below 100 kilohertz are suited for fabrication utilizing laminated steel cores such as shown in the cross-sections of **FIGs. 6** through **15**. For inductors used in a frequency range of 100 kilohertz to 5 megahertz, a ferrite core is desirable. However, ferrite cores are fragile and prone to breakage when stress, e.g. bending for product fabrication and bending for assembly processing, is applied.

Referring to **FIG. 20a**, the principle of inductor construction, for the flexible circuit assembly of the present invention, is applied to provide a stable and

somewhat flexible device configuration. Ferrite core **248**, having air gap **246**, is sandwiched between steel lamination core layers **240** and **252**, the cores having air gaps **242** and **254**, respectively. Intervening adhesive layers **244** and **250** provide an attachment mechanism for laminating the steel core layers to the ferrite core layer. Air gaps **242** and **254** are located in a predetermined offset fashion, on the same side of the steel cores for this example. The air gap for the ferrite core is located, in a predetermined position, on the opposite side that of the air gaps for the steel cores so as to provide a balanced degree of stress relief for the laminated ferrite core inductor structure.

For example, the amorphous steel clad core layers each are 0.018 mm thick, the adhesive layers are each 0.025 mm thick, and the ferrite core is 0.135 mm thick. The ferrite core and steel air gaps are cut at 0.04 mm wide. The resulting inductance, when configured as the inductor of **FIG. 1**, is approximately 20 micro Henries, when operated at frequencies in the low megahertz range.

Referring to **FIG. 21**, cuts are made along respective cut lines **212** shown in **FIG. 1**. In **FIG. 1**, flexible circuit assembly **30** is, for example, singulated from a roll of multiple assembled flexible assemblies (not shown). Cuts are made along peripheral cut lines **214** in the singulation process. The cuts are made with a router cutting tool or other cutting device as one skilled in the art would recognize. Cuts are next made in a longitudinal direction along cut lines **212**. The cuts are terminated at their respective drill openings **218**. The drill openings serve as termination points to minimize cutting tool tear-out at the end of the cut lines.

The columns of LED devices and longitudinal metallizations are now slightly separated. To accommodate cutting along lateral cut line **215** to serve as a separation line for inductor area **130**.

Referring back to **FIG. 21**, the cut flexible assembly is now further separated and spread to form post cut longitudinal areas **222** and post cut lateral area **225**. The resulting flexible structure **300** is ribbon-like and exhibits a high degree of flexibility, approaching a 360 degree bendable capability and configurable in three dimensions.

Looking now to **FIG. 22**, flexible structure **300**, and from flexible structure **300** of **FIG. 21**, is affixed to cylindrical canister **150**. The attachment mechanism

is, for example, but not limited to a mechanical means, e.g., screws or bolts; or adhesive means, e.g., tape, adhesive laminate layer, glue, thermally conductive gel, or epoxy; or hard fixed means, e.g., solder or welding.

For this application the flexible structure-canister combination forms an
5 electric LED lighting device, powered directly by an alternating current (AC)
source. The canister further operates to provide a heat sink for the conforming
flexible structure. The cylindrical canister is, but not limited to aluminum, copper,
brass, or steel. The thickness of the canister material is selected to provide an
appropriate heat sinking heat transfer mechanism for the dissipating heat
10 generated by LEDs in the flexible circuit assembly.

Thus, by cutting and then spreading the flexible circuit assembly of **FIG. 21**,
heat generated by the components of the assembly, is likewise spread over a
greater area to improve thermal dissipation characteristics of the AC powered,
transformer coupled, LED string.

15 For this example, the total weight of the canister assembly is 112 grams,
i.e., 103 grams for the aluminum canister plus 9 grams for the flexible circuit
assembly, thus providing an ultra lightweight LED lighting appliance weighing less
than $\frac{1}{4}$ of a pound.

INDUSTRIALIZATION

The present invention is designed for phasing into high volume production.

5 Initially, the flexible circuit assembly is processed in rectangular panels to provide a vehicle to improve and optimize materials, processes, design, test and quality.

Once processes are optimized, manufacturing will transition from panels to roll-to-roll processes. Dielectric films as polyimide, polyester-imide, polyester, impregnated paper and conductive foils of copper, aluminum and steel are
10 available in rolls of 300 mm width and wider.

Combined tools, developed by equipment integrators, are available to cut films, to laminate two or more layers, to print, to chemically etch, and to deposit thin metal on continuous roll of thin films. High speed, automated tools for roll-to-roll manufacturing lines can be further integrated to pick and place components,
15 e.g., magnetic cores and islands.

Additionally, devices, e.g., semiconductors, LEDs, diodes, capacitors, resistors, lenses, and adhesives, encapsulants, thermally conductive gels, and skive, are integrated into roll of laminated, thin films. Near the end of process, the roll of embedded electronics is electrically tested, and is inspected and cut to
20 singulate out a complete electronic system such as low cost LED lighting. The goal is low cost, thin, flexible, light weight, power electronics for medical, aerospace, automotive, hand-held and other applications.

Thus it can now be appreciated that the present invention provides a method for fabricating a highly flexible circuit assembly by removing material in
25 predetermined locations in an intermediate layer of the assembly.

It can be further appreciated that the present invention provides reduced stress characteristics for devices by locating devices at, or in proximity to, a zero stress plane of the flexible circuit assembly.

It can be even further appreciated that the embedded devices include a
30 three dimensional inductor with magnetic field planes parallel to the plane of the flexible circuit assembly, thus reducing the effects of stray magnetic fields on other devices within the assembly.

It can be still further appreciated that the present invention provides a method for reducing stress within a laminated magnetic core of an inductor embedded in the flexible circuit assembly by locating a brittle ferrite core in proximity to the low stress central plane.

5 It can be even more so appreciated that the present invention provides a structure for enhanced heat dissipation for embedded devices within the flexible circuit assembly.

It can also be appreciated that the present invention is highly compatible with low cost and automated roll-to-roll manufacturing techniques.

10 It can additionally appreciated that the present invention combines light weight with conformability for the flexible circuit assembly.

In the foregoing specification, the invention has been described with reference to specific embodiments, to specific materials, to specific processes, and to specific specifications. While specific embodiments of the present invention
15 have been shown and described, further modifications and improvements will occur to those skilled in the art. It is understood that the invention is not limited to the particular forms illustrated, and it is intended for the appended claims to cover all modifications that do not depart from the spirit and the scope of this invention.

CLAIMS

I claim:

- 5 1. A flexible circuit assembly, having an embedded device, comprising:
an intermediate layer having an opening configured for receiving an
embedded device,
said intermediate layer having a first and second surface,
said embedded device having a mid-plane plane;
10 a first structure having a first layer and a second layer, said first layer of
said first structure affixed to said first surface of said intermediate
layer,
said first structure having intervening layers between said first layer
and said second layer,
15 said first structure having an opening through said first layer, through
said second layer, and through said intervening layers, said
opening concurrent with said intermediate layer opening, and
configured for embedding said embedded device; and
a second structure having a first layer and a second layer, said first layer of
20 said second structure affixed to said second surface of said
intermediate layer,
said second structure having intervening layers between said first
layer and said second layer of said second structure,
said second structure having a opening for device target placement
25 through said first layer, through said intervening layers, and
terminating at said first layer of said second structure,
said opening of said second structure being concurrent with
said opening of said intermediate layer opening and
said opening of said first structure,
30 said embedded device placed through said opening of said
second structure and having a first surface affixed to
said first layer of said second structure,

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said intermediate layer, said first structure, and said second structure in combination, having a predetermined central plane;

said mid-plane of said embedded device located in proximity to said central plane of said intermediate layer.

5

2. The flexible circuit assembly, having an embedded device, of claim 1, wherein said first surface of said embedded device is configured for coupling to metallization interconnect within said second structure.
3. The flexible circuit assembly, having an embedded device, of claim 1, further comprising a second surface of said embedded device, said second surface of said embedded device configured for coupling to metallization interconnect within said first structure.
4. The flexible circuit assembly, having an embedded device, of claim 1, wherein said embedded device is a light emitting diode (LED).
- 15 5. The flexible circuit assembly, having an embedded device, of claim 1, wherein said embedded device is covered by a protective encapsulant.
6. The flexible circuit assembly, having an embedded device, of claim 1, wherein a heat sink is affixed to a predefined area of said second layer of said first structure, on a surface opposite to said embedded device placement surface.
- 20 7. A flexible circuit assembly, having an embedded device, comprising:
 - an intermediate layer having an opening configured for receiving an embedded device,
 - said intermediate layer having a first and second surface,
 - 25 said embedded device having a mid-plane plane;
 - a first structure having a first layer and a second layer, said first layer of said first structure affixed to said first surface of said intermediate layer,
 - said first structure having intervening layers between said first layer and said second layer;
 - 30

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- a second structure having a first layer and a second layer, said first layer of said second structure affixed to said second surface of said intermediate layer,
said second structure having intervening layers between said first
5 layer and said second layer of said second structure;
said intermediate layer, said first structure, and said second structure combined, having a central plane, and
said embedded device placed through said opening of said intermediate layer and having a first surface affixed to said first layer of said
10 second structure,
wherein said first surface of said embedded device is configured for coupling to metallization interconnect within said second structure,
said embedded device having a second surface, said second
15 surface of said embedded device configured for coupling to metallization interconnect within said first structure.
8. The flexible circuit assembly, having an embedded device, of claim 7, wherein a heat sink is affixed to a predefined area of said second layer of said first structure, in opposition to said embedded device placement.
20
9. The flexible circuit assembly, having an embedded device, of claim 7, wherein said embedded device is an inductor.
10. The flexible circuit assembly, having an embedded device, of claim 7, wherein said mid-plane of said embedded device is located in proximity to said central plane of said intermediate layer.
25
11. A method of improving stress relief for an embedded device in a flexible circuit assembly, comprising the steps of:
a) selecting a device for embedding;
b) providing an intermediate layer with predetermined openings for
30 placement of said device for embedding, said intermediate layer having a first surface and a second surface,

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1. enlarging said predetermined openings in areas of desired mechanical stress relief for said device,
 2. minimizing said predetermined openings around said device in areas of desired mechanical support;
- 5 c) forming a first structure having a first layer and a second layer with intervening layers there between,
- d) affixing said first layer of said first structure to said second surface of said intermediate layer;
- 10 e) providing a predetermined opening in a predetermined area in said first layer and said intervening layers in said first structure, in said first structure, exposing said second layer to said predetermined area;
- f) forming a second structure having a first layer and a second layer with intervening layers there between,
- 15 1. providing an opening in said first layer and said intervening layers of said second structure for mounting accessibility for said device;
- g) affixing said device upon said exposed second layer of a second structure; and
- 20 h) providing interconnect for said device to said first and second structures.
12. A method of improving stress relief for an embedded device in a flexible circuit assembly, comprising the steps of:
- 25 a) selecting a device for embedding;
- b) providing an intermediate layer with predetermined openings for placement of said device for embedding, said intermediate layer having a first surface and a second surface,
- 30 1. enlarging said predetermined openings in areas of desired mechanical stress relief for said device,
2. minimizing said predetermined openings around said device in areas of desired mechanical support;

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- 5
- c) providing a first structure having a first layer and a second layer with intervening layers there between;
 - d) affixing said first layer of said first structure to said second surface of said intermediate layer;
 - e) embedding said device through said opening in said intermediate opening;
 - f) affixing said embedded device to said first layer of said first structure
 - 10 g) providing a second structure having a first layer and a second layer with intervening layers there between;
 - h) affixing said first layer of said second structure to said first surface of said intermediate layer; and
 - i) providing interconnect for said device to said first and second structures.
- 15 13. A method of reducing stress for an embedded device in a flexible circuit assembly, comprising the steps of:
- a) selecting a device for embedding;
 - b) determining a mid-plane for said device;
 - c) determining a central plane for a flexible circuit assembly
 - 20 d) providing an intermediate layer with predetermined openings for placement of said device for embedding in a predetermined area;
 - 1. said intermediate layer having a first surface and a second surface;
 - 25 e) providing a first structure having a first layer and a second layer with intervening layers there between;
 - f) affixing said first layer of said first structure to said second surface of said intermediate layer;
 - 30 g) providing a predetermined opening in said first layer and said intervening layers, of said first structure, exposing said second layer to said predetermined area;

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- h) providing a second structure having a first layer and a second layer with intervening layers there between,
1. providing an opening in said second structure for mounting accessibility for said device;
- 5 i) affixing said first layer of said second structure to said first surface of said intermediate layer;
- j) affixing said device upon said exposed second layer of said first structure wherein said mid-plane of said device is in proximity to said central plane of said flexible circuit assembly; and
- 10 k) providing interconnect for said device to said first and second structures.
14. A method of reducing stress for an embedded device in a flexible circuit assembly, comprising the steps of:
- 15 a) selecting a device for embedding,
b) determining a mid-plane for said device;
c) determining a central plane for a flexible circuit assembly
d) providing an intermediate layer with predetermined openings for placement of said device for embedding,
20 1. said intermediate layer having a first surface and a second surface;
- e) providing a first structure having a first layer and a second layer with intervening layers there between;
- 25 f) affixing said first layer of said first structure to said second surface of said intermediate layer;
- g) providing a predetermined opening in said first layer and said intervening layers, of said first structure, exposing said second layer to said predetermined area;
- 30 h) providing a second structure having a first layer and a second layer with intervening layers there between;

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- i) affixing said first layer of said second structure to said first surface of said intermediate layer;
 - j) providing an opening in said second structure for mounting accessibility for said device;
 - 5 k) affixing said device upon said first layer of said second structure wherein said mid-plane of said device is in proximity to said central plane of said flexible circuit assembly; and
 - l) providing interconnect for said device to said first and
10 second structures
15. A method of fabricating a laminated inductor core, suitable for embedding in a flexible circuit assembly, comprising the steps of:
- a) patterning a first magnetic core layer;
 - b) patterning a second magnetic core layer;
 - 15 c) forming said first magnetic core layer;
 - d) forming said second magnetic core layer;
 - e) forming an air gap in said first magnetic core layer;
 - f) forming an air gap in said second magnetic core layer,
wherein said air gap in said second magnetic core layer is
20 offset from said air gap in said first magnetic core layer; and
 - g) laminating said first and second magnetic core layers.
16. The method of fabricating a laminated inductor core as recited in claim 15, wherein said laminating of said first and second magnetic core layers is performed prior to the steps said forming of said first and second magnetic
25 core layers, and after the steps of said patterning of said first and second magnetic core layers..
17. The method of fabricating a laminated inductor core as recited in claim 15, wherein said forming of said first and second magnetic core layers is performed by etching.
- 30 18. The method of fabricating a laminated inductor core as recited in claim 15, wherein said forming of said first and second magnetic core layers is performed by laser cutting.

19. The method of fabricating a laminated inductor core as recited in claim 15, wherein said forming of said air gaps for said first and second magnetic core layers is performed by laser cutting.
20. A method of fabricating a laminated inductor core, suitable for embedding in
5 a flexible circuit assembly, comprising the steps of:
- a) patterning a first magnetic core layer;
 - b) patterning a second magnetic core layer;
 - c) patterning a third magnetic core layer;
 - d) forming said first magnetic core layer;
 - 10 e) forming said second magnetic core layer;
 - f) forming said third magnetic core layer;
 - g) forming an air gap in said first magnetic core layer;
 - h) forming an air gap in said second magnetic core layer,
wherein said air gap in said second magnetic core layer is
15 offset from said air gap in said first magnetic core layer; and
 - i) laminating said first, second, and third magnetic core layers
wherein said third magnetic core layer is sandwiched
between said first and second magnetic core layers..
21. The method of fabricating a laminated inductor core as recited in claim 20,
20 wherein said forming of said first, second, and third magnetic core layers is performed by laser cutting.
22. The method of fabricating a laminated inductor core as recited in claim 20, wherein said third magnetic core layer is a ferrite core layer.
23. The method of fabricating a laminated inductor core as recited in claim 20,
25 further comprising the step of forming an air gap in said third magnetic core layer.
24. A method of further enhancing flexibility in a flexible circuit assembly,
comprising the steps of:
- a) providing a flexible circuit assembly,
 - 30 b) predetermining a plurality of cut lines for said flexible circuit assembly;

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- 5
- c) providing a plurality of termination points for said plurality of cut lines;
 - d) cutting said flexible circuit assembly along said each of said predetermined cut lines to corresponding said termination points; and
 - e) separating said flexible circuit assembly along at least one of said cut lines in an expanding manner..
- 10
25. A flexible circuit assembly, having an embedded light emitting diode (LED), comprising:
- an intermediate layer having an opening configured for receiving a light emitting diode,
- said intermediate layer having a first and second surface,
- said light emitting diode having a mid-plane plane;
- 15 a first structure having a first layer and a second layer, said first layer of said first structure affixed to said first surface of said intermediate layer,
- said first structure having intervening layers between said first layer and said second layer,
- 20 said first structure having an opening through said first layer, through said second layer and through said intervening layers, said opening concurrent with said intermediate layer opening and configured for embedding of said light emitting diode; and
- a second structure having a first layer and a second layer, said first layer of
- 25 said second structure affixed to said second surface of said intermediate layer,
- said second structure having intervening layers between said first layer and said second layer of said second structure,
- said second structure having a device placement opening through
- 30 said first layer, through said intervening layers, and terminating at said second layer of said first structure,

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- said device placement opening configured for receiving said light emitting diode
- said device placement opening of said second structure being concurrent with said opening of said intermediate layer opening and said opening of said first structure,
- 5 said light emitting diode placed into said device placement opening and having a first surface affixed to said first surface of said second layer of said second structure, said intermediate layer, said first structure, and said second structure
- 10 in combination, having a predetermined central plane, said mid-plane of said light emitting diode located in proximity to said central plane of said intermediate layer in said flexible circuit assembly; and
- said light emitting diode configured for coupling to metallization
- 15 interconnects of said flexible circuit assembly.
26. The flexible circuit assembly, having an embedded light emitting diode (LED), of claim 25, wherein said embedded device is configured for coupling to metallization interconnect within said first structure.
27. The flexible circuit assembly, having an embedded light emitting diode
- 20 (LED), of claim 25, wherein said embedded device is configured for coupling to metallization interconnect within said second structure
28. The flexible circuit assembly, with an embedded light emitting diode, of claim 25, wherein said embedded device is covered by a protective encapsulant.
- 25 29. The flexible circuit assembly, having an embedded light emitting diode (LED), of claim 25, further comprising a first coverlay layer for protecting said flexible circuit assembly;
- said first coverlay layer affixed to a first surface of said second layer of said first structure; and
- 30 said first coverlay having an opening concurrent with said opening of said first structure to accommodate insertion of said light emitting diode during the embedding process.

30. The flexible circuit assembly, having an embedded light emitting diode (LED), of claim 25, further comprising a second coverlay layer for protecting said flexible circuit assembly;
- 5 said second coverlay layer affixed to a second surface of said second layer of said first structure; and
- said second coverlay having an opening opposite to said die placement opening for exposing said second layer of said second structure for effecting heat transfer from said embedded light emitting diode.
- 10 31. A flexible circuit assembly, with an embedded inductor device, comprising:
a flexible circuit assembly having an intermediate layer having an opening configured for receiving an inductor core,
 said intermediate layer having a first and second surface;
a first structure having a first layer and a second layer,
- 15 said first structure having an opening to facilitate the embedding of said inductor core,
 said first structure having intervening layers between said first layer and said second layer, wherein one of said intervening layers of said first structure is configured for providing a plurality of
- 20 top windings for said inductor core;
a second structure having a first layer and a second layer,
 said first layer of said second structure affixed to said second surface of said intermediate layer,
 said second structure having intervening layers between said first
- 25 layer and said second layer, wherein one of said intervening layers of said second structure is configured for providing a plurality of bottom windings for said inductor core;
said inductor core affixed to said first surface of said intermediate layer through said through said opening of said first structure and through
- 30 said opening of said intermediate layer;
said first layer of said first structure affixed to said first surface of said intermediate layer;

said flexible circuit assembly having a plurality of plated vias passing through said first structure, said intermediate layer, and said second structure for coupling said plurality of top windings and to said plurality of bottom windings to provide inductor loops for said inductor core to complete the embedded inductor device; and
5 said top windings and said bottom windings further configured for coupling to an input signal and to an output signal of said embedded inductor device.

32. A circuit for powering a light emitting diode (LED) with an alternating
10 current, comprising:
a plurality of light emitting diode pairs coupled in a serial configuration,
each of said light emitting diode pairs having a first diode, said first diode having an anode and a cathode,
each of said light emitting diode pairs having a second diode, said
15 second diode having an anode and a cathode,
wherein said cathode of said first diode is coupled to said anode of said second diode,
wherein said cathode of said second diode is coupled to said anode of said first diode;
20 a first light emitting diode pair having an input at a juncture of said first diode anode and said second diode cathode;
a second light emitting diode pair have an input at a juncture of said first diode cathode and said second anode cathode,
a remainder of said plurality of said light emitting diode pairs coupled
25 between said first light emitting diode pair and said second light emitting diode pair;
a transformer having a first output coupled to said input of said first light emitting diode pair and a second output coupled to said input of said second light emitting diode pair; and
30 said transformer having a first input and a second input, said first and second inputs configured for coupling to an alternating current source.

33. The circuit for powering light emitting diodes (LED) with an alternating current of claim 32, wherein said plurality of said light emitting diode pairs is a single diode pair.
34. The circuit for powering light emitting diodes (LED) with an alternating current of claim 32, wherein said light emitting diodes and said transformer are integrated into a flexible circuit assembly.
- 5 35. A circuit for powering a light emitting diode (LED) with an alternating current, comprising:
- 10 a first light emitting diode string comprising a plurality of light emitting diodes coupled in an cathode to anode configuration, said first light emitting diode string having an anode end and a cathode end;
 - a first diode having an anode coupled to said cathode end of said light emitting diode string,
 - 15 said first diode having a cathode;
 - a second light emitting diode string comprising a plurality of light emitting diodes coupled in an cathode to anode configuration, said second light emitting diode string having an anode end and a cathode end;
 - 20 a second diode having an cathode coupled to said anode end of said second light emitting diode string, said first diode having an anode;
 - a transformer having a first output coupled to said cathode of said first diode and to said anode of said second diode,
 - 25 said transformer having a second output coupled to said anode end of said first light emitting diode string and to said cathode of said second diode; and
 - said transformer having a first input and a second input, said first and second inputs configured for coupling to an alternating current
 - 30 source.

36. The circuit for powering light emitting diodes (LED) with an alternating current of claim 35, wherein said light emitting diodes and said transformer are integrated into a flexible circuit assembly.

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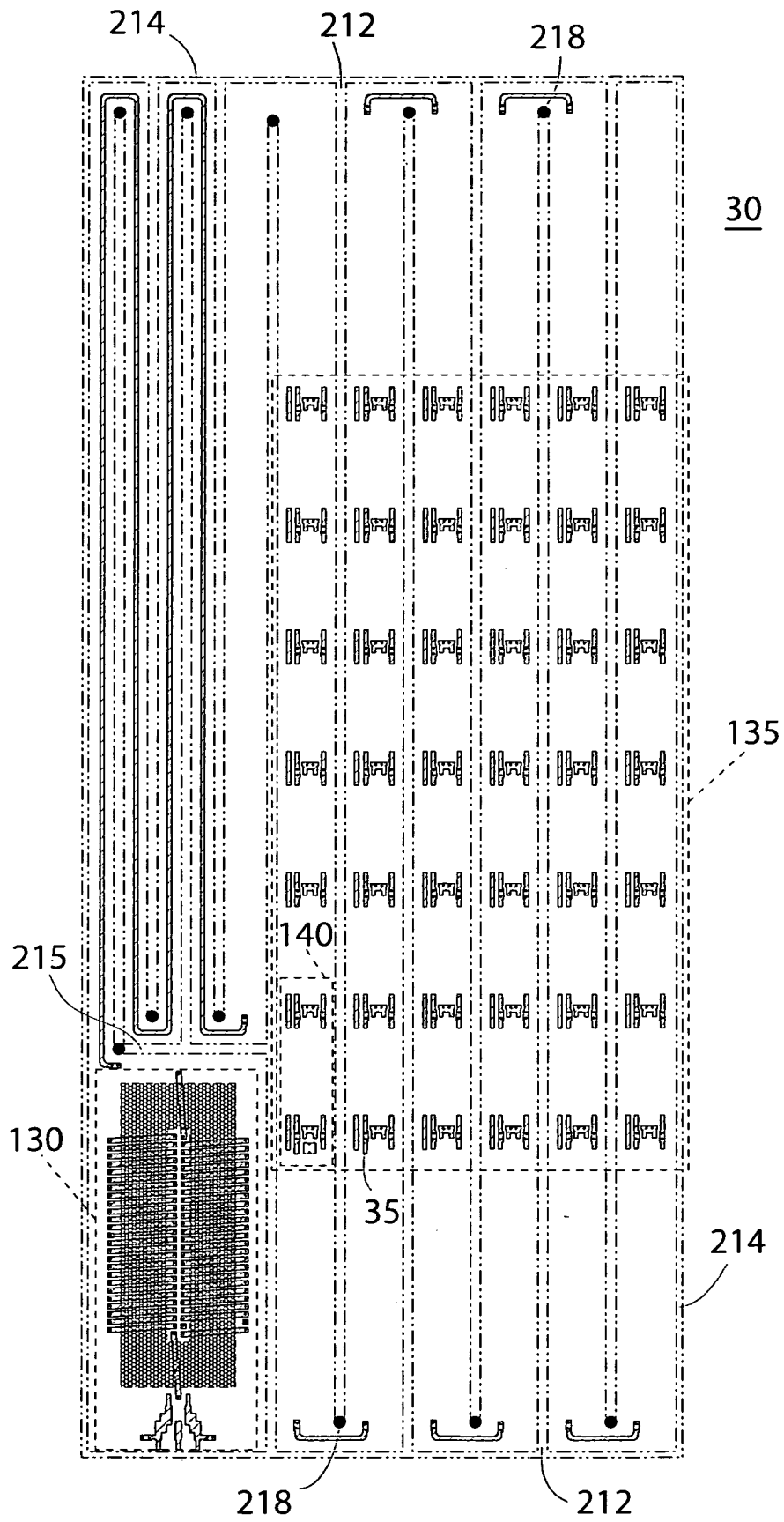


FIG. 1

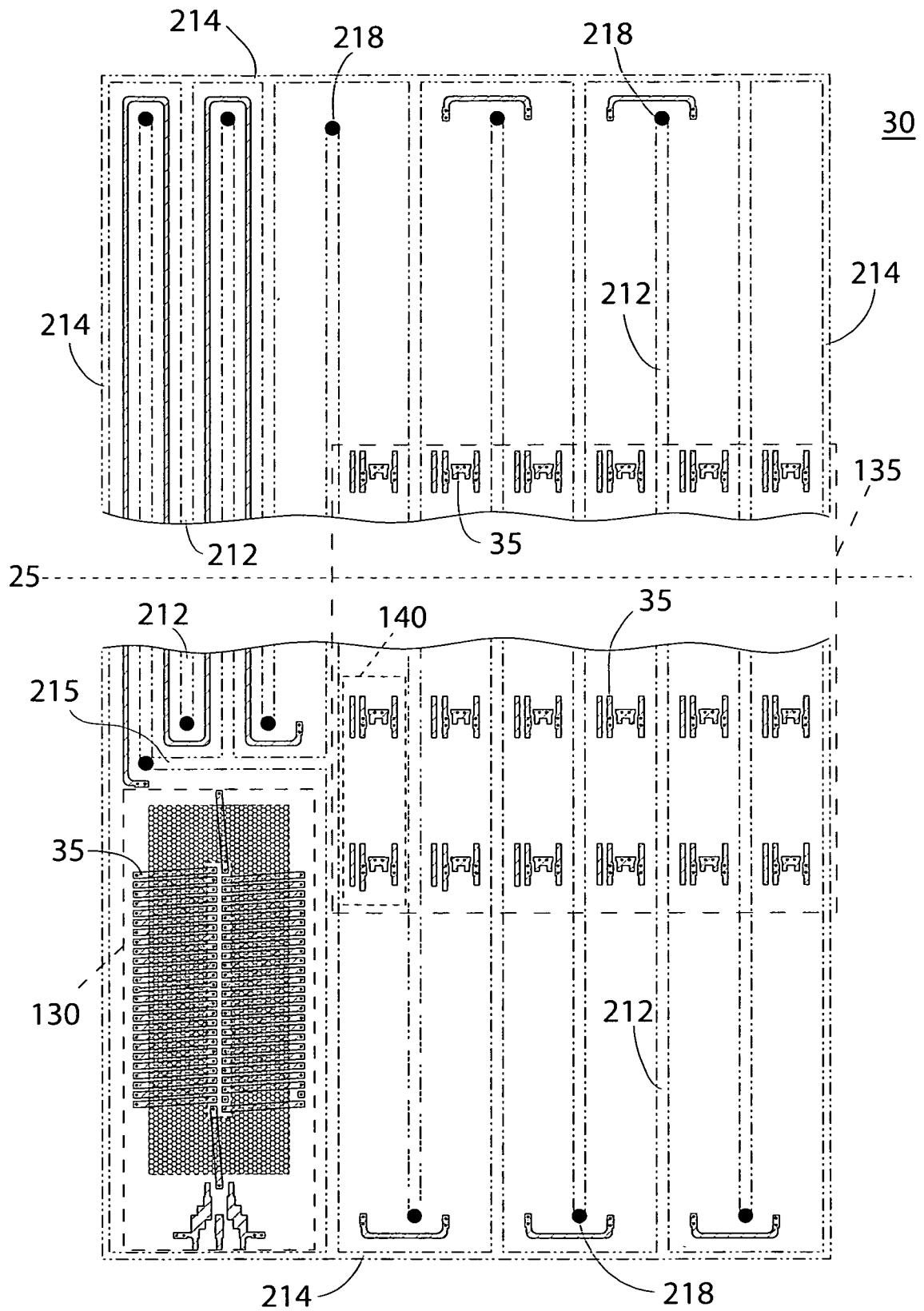


FIG. 1a

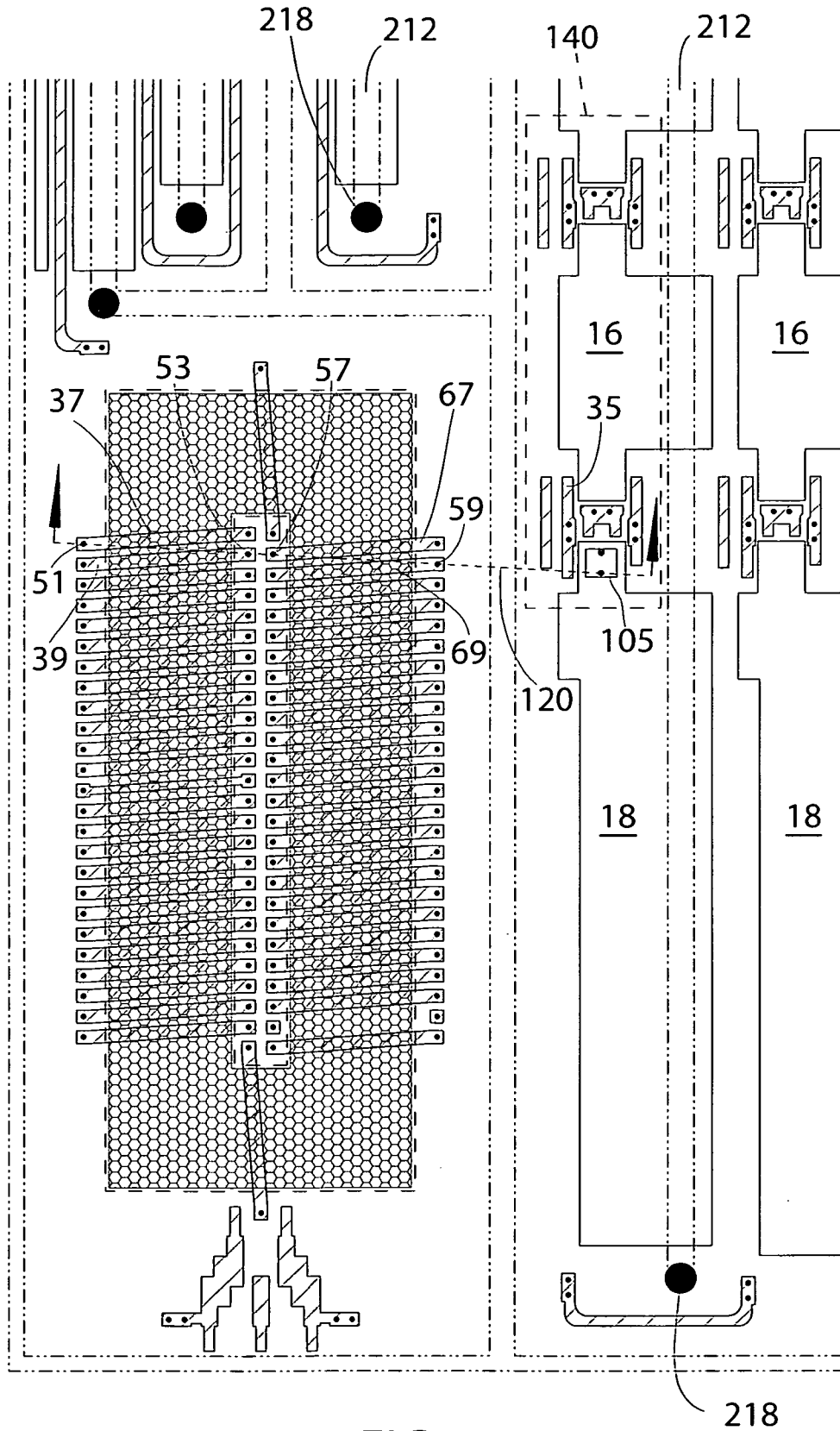


FIG. 2

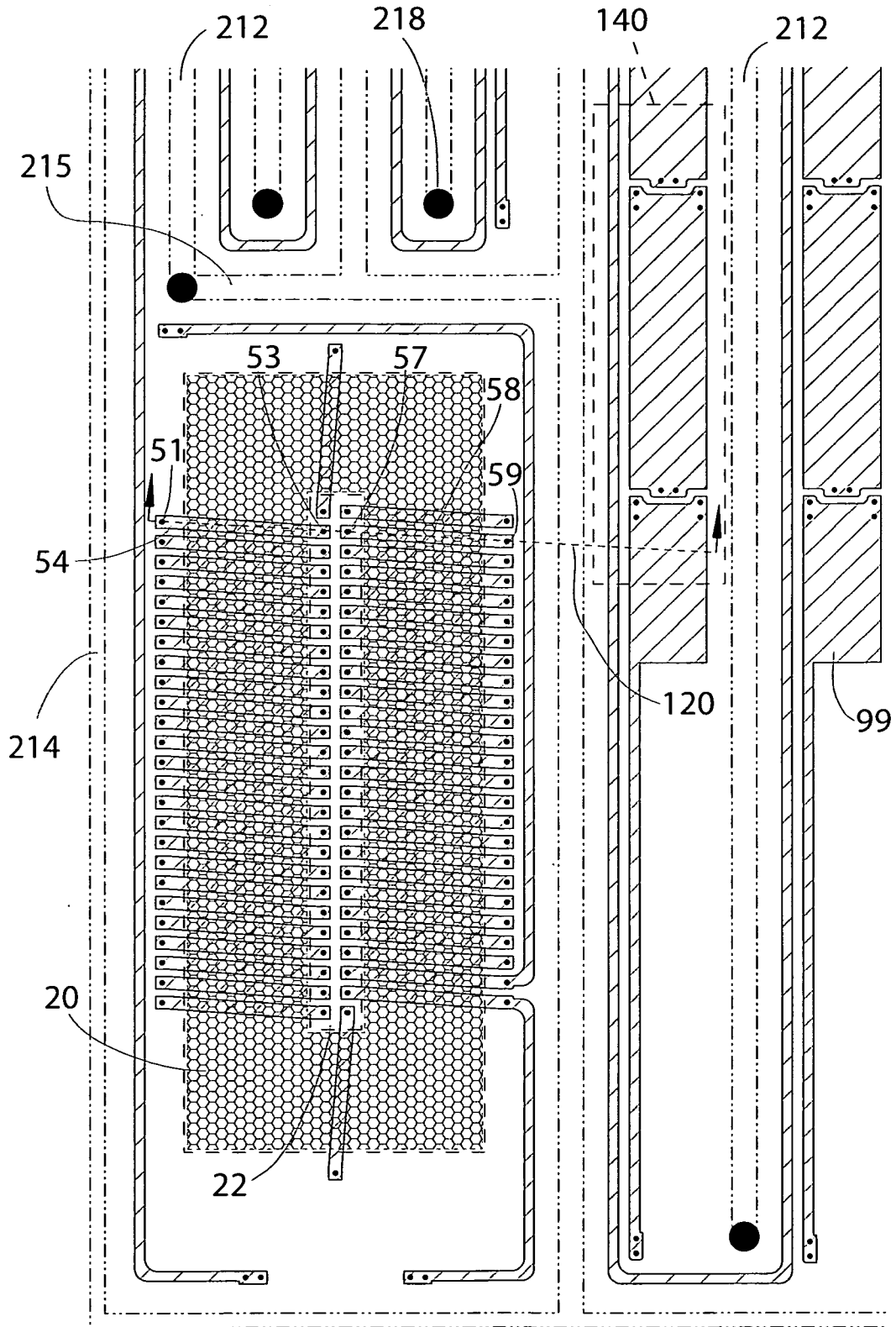


FIG. 3

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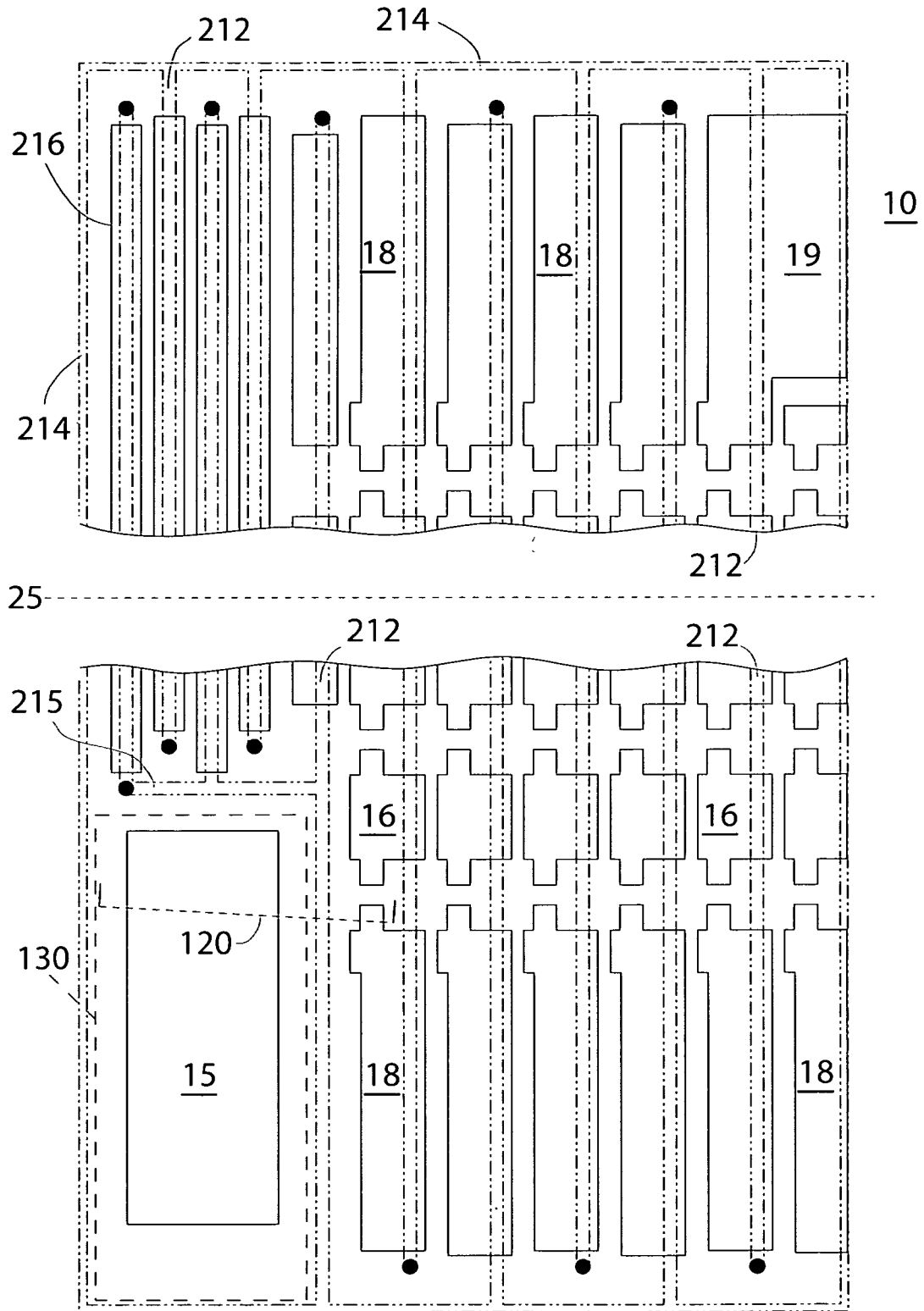


FIG. 4

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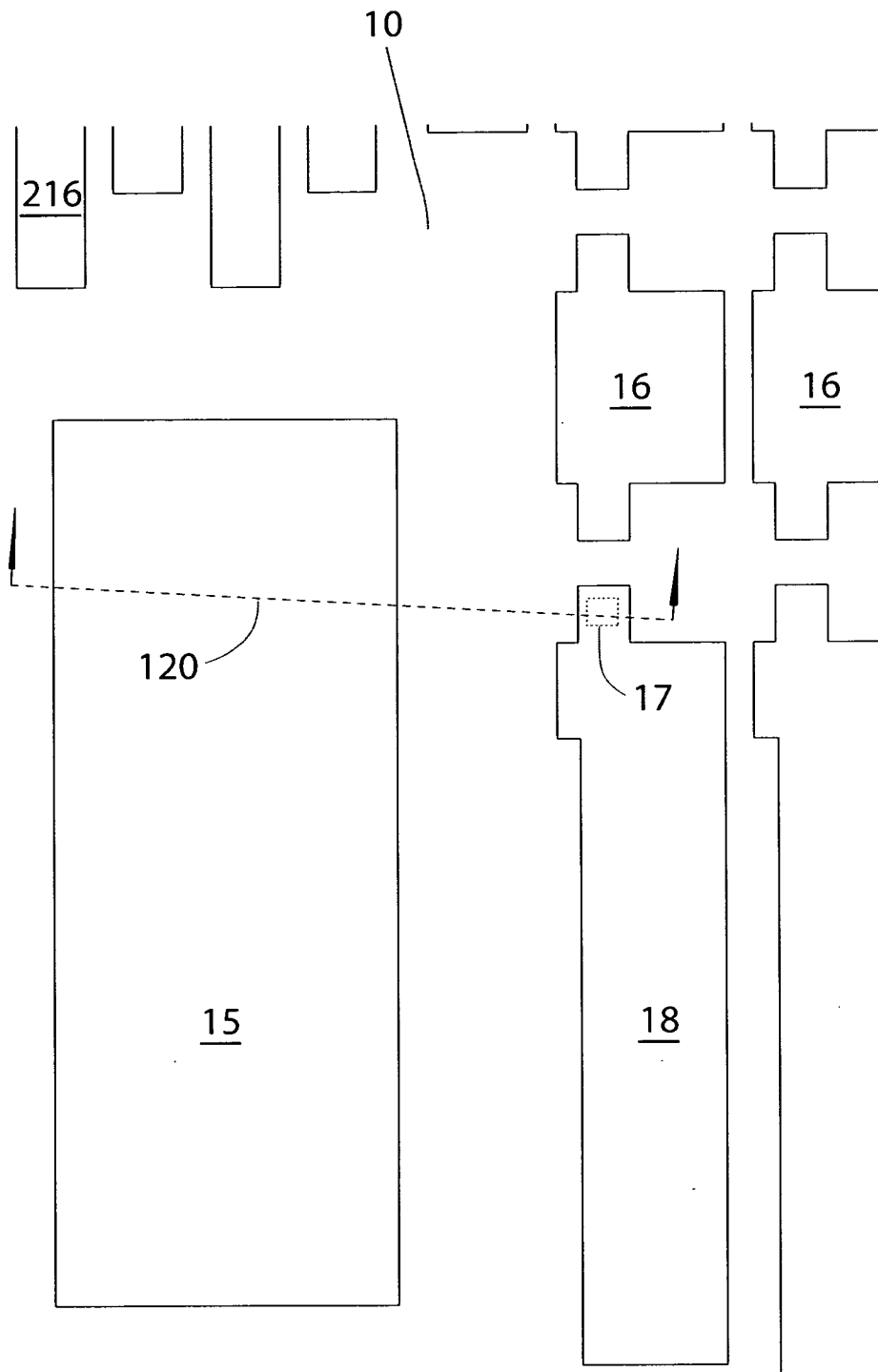


FIG. 5

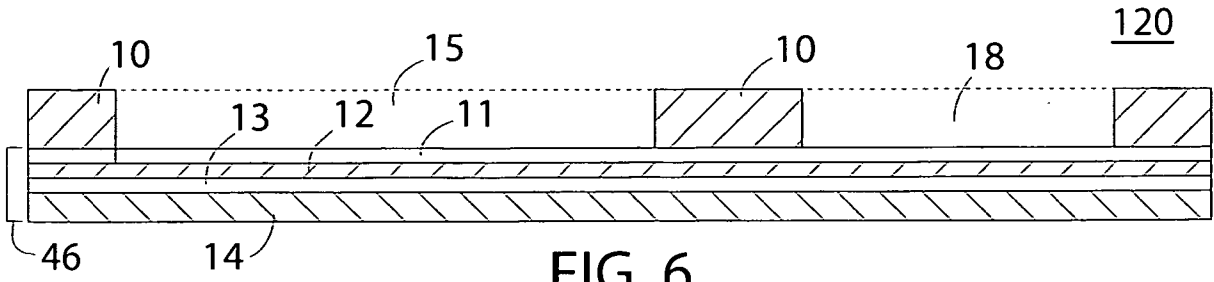


FIG. 6

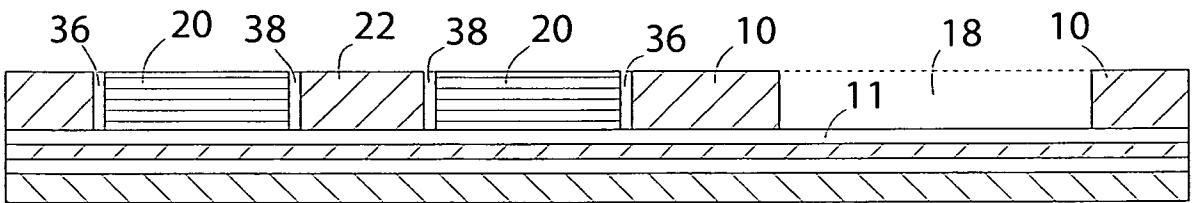


FIG. 7

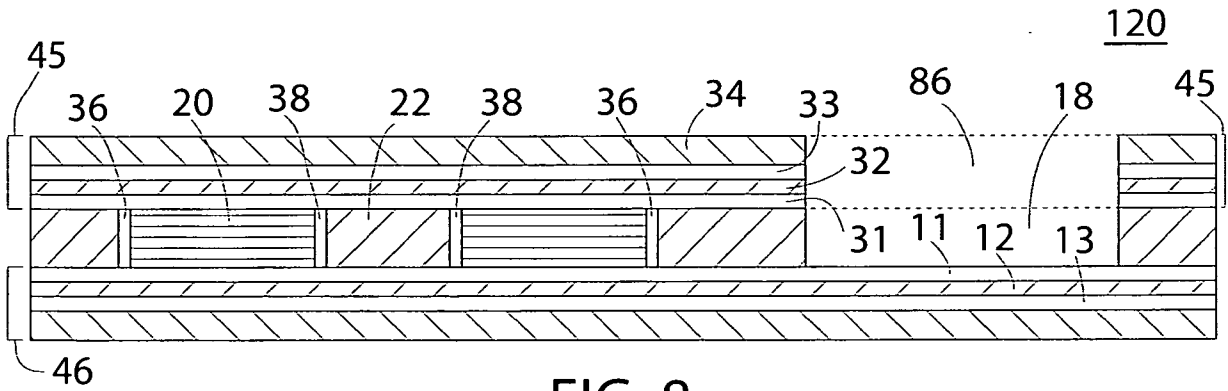


FIG. 8

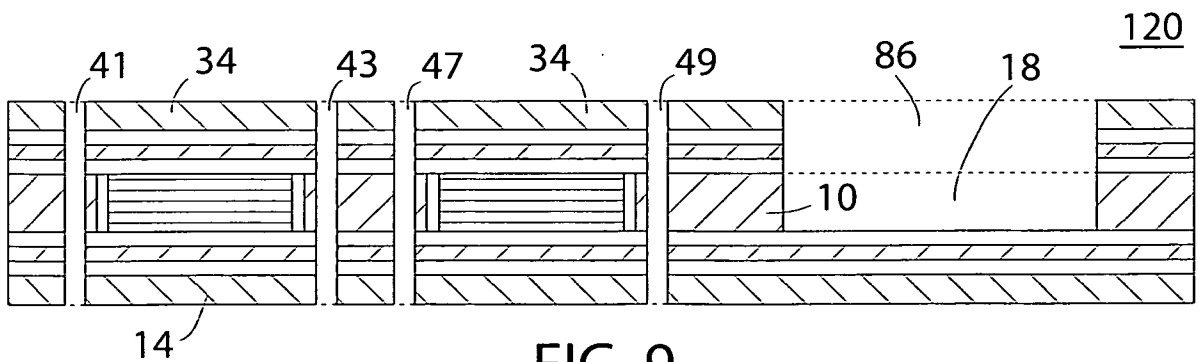


FIG. 9

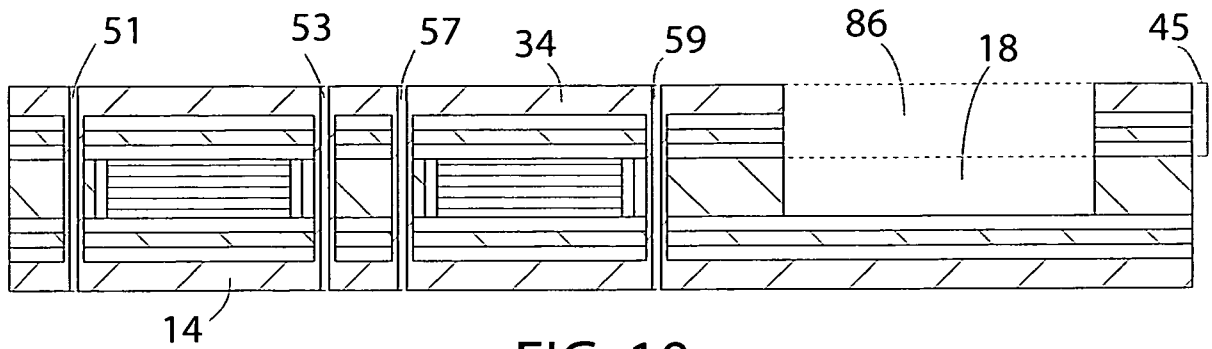


FIG. 10

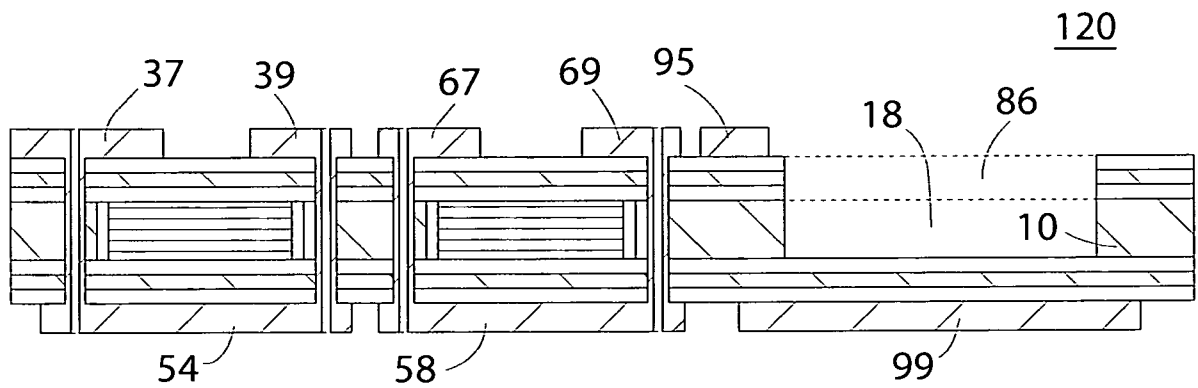


FIG. 11

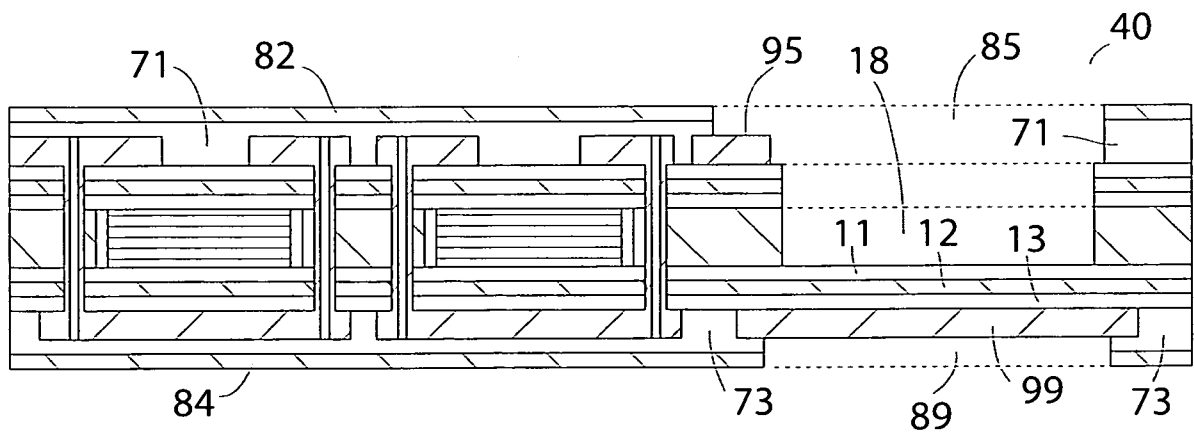


FIG. 12

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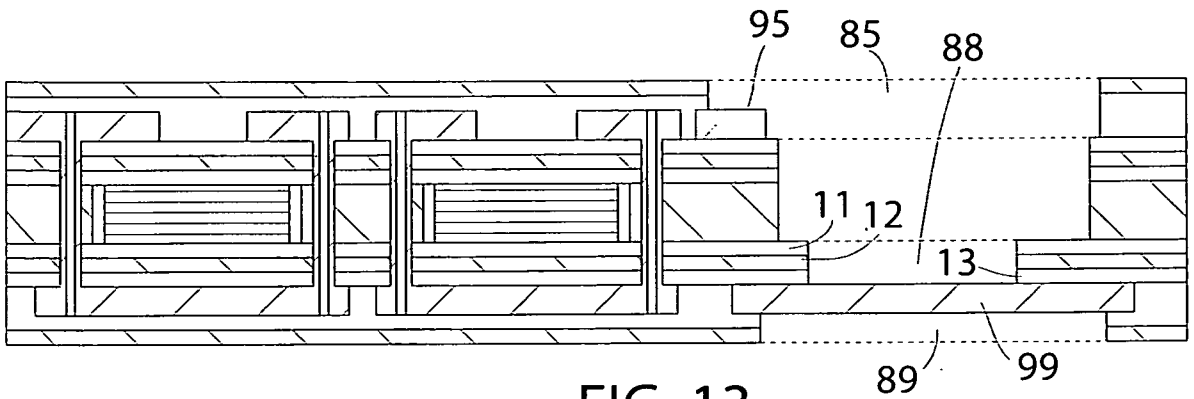


FIG. 13

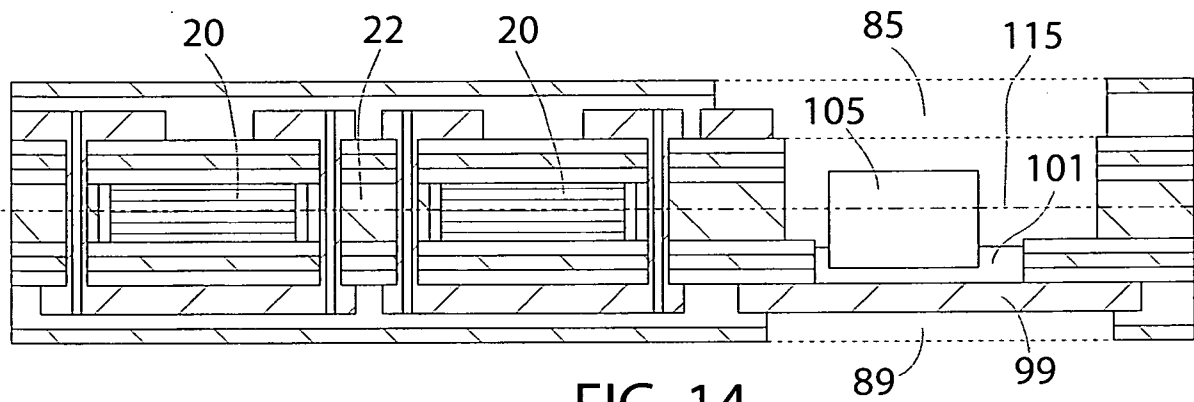


FIG. 14

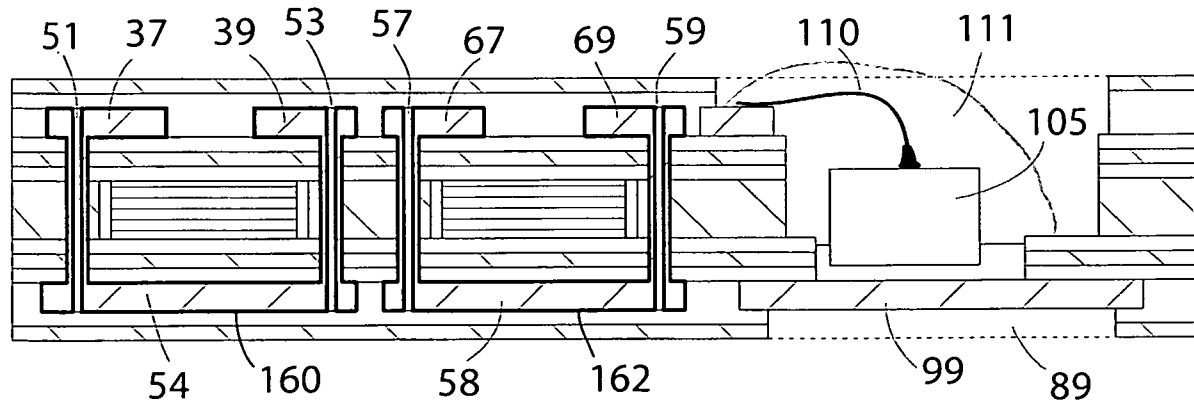


FIG. 15

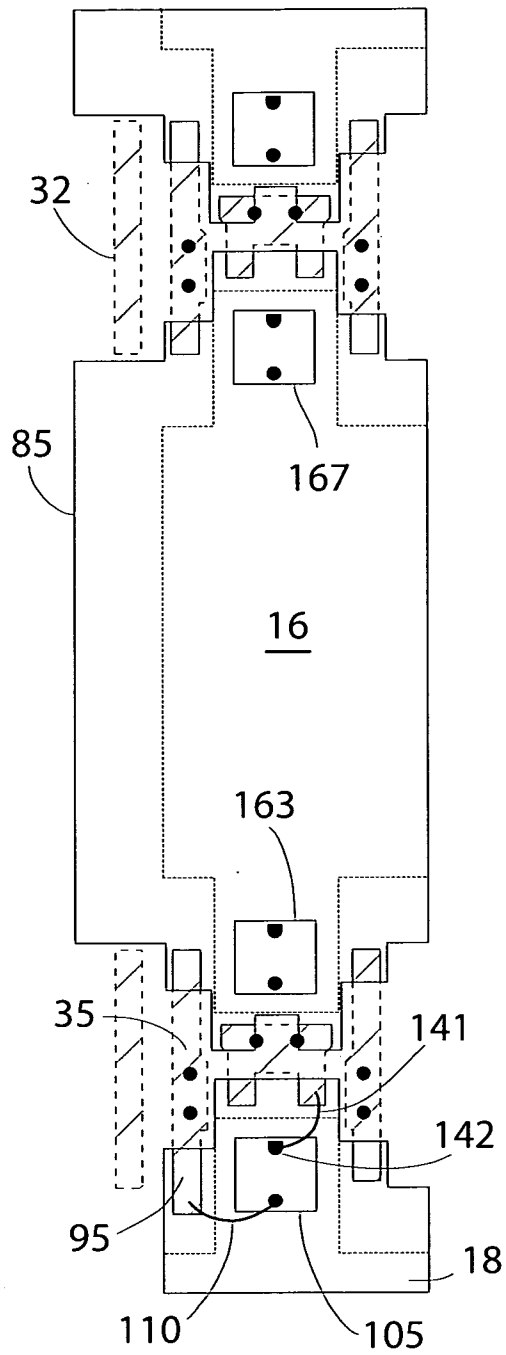


FIG. 16

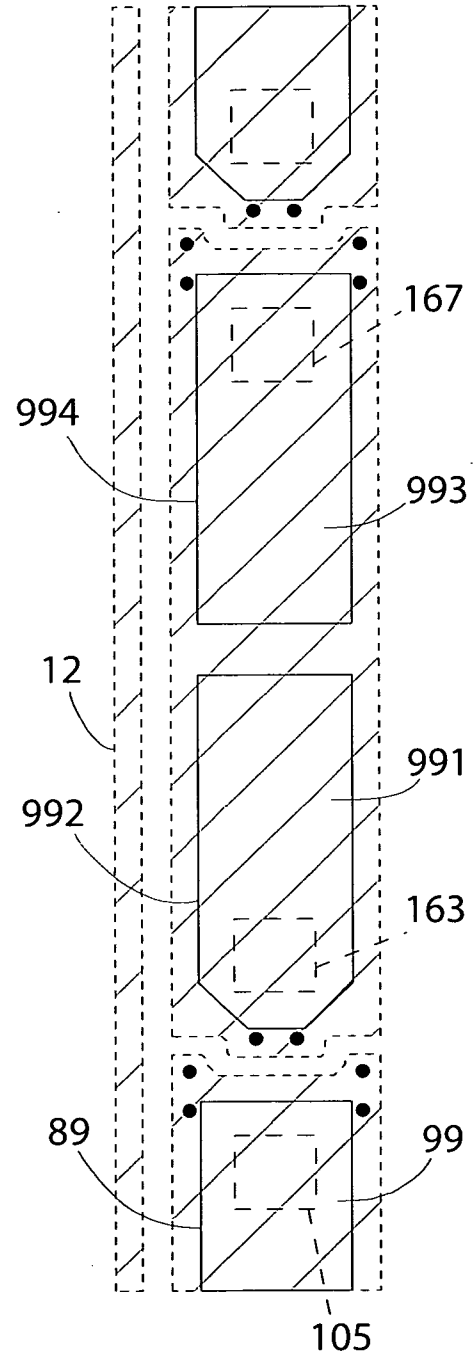


FIG. 17

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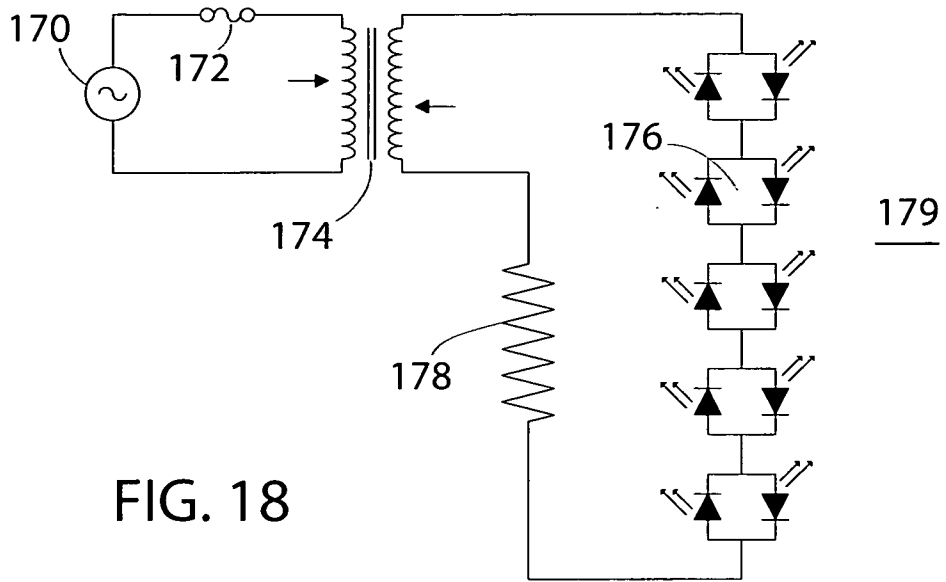


FIG. 18

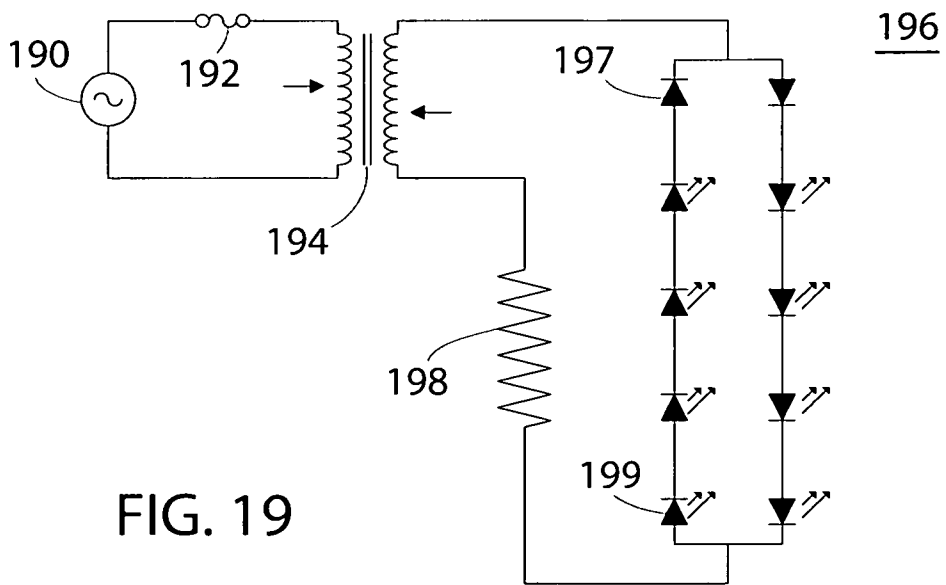


FIG. 19

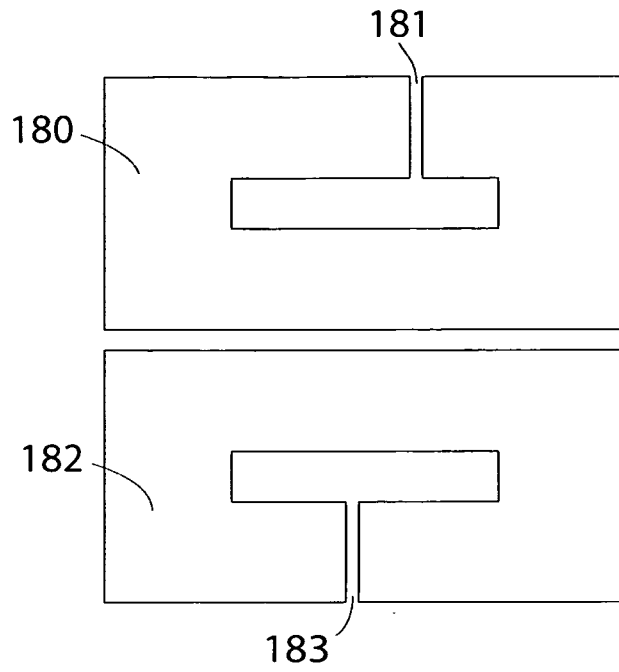


FIG. 20

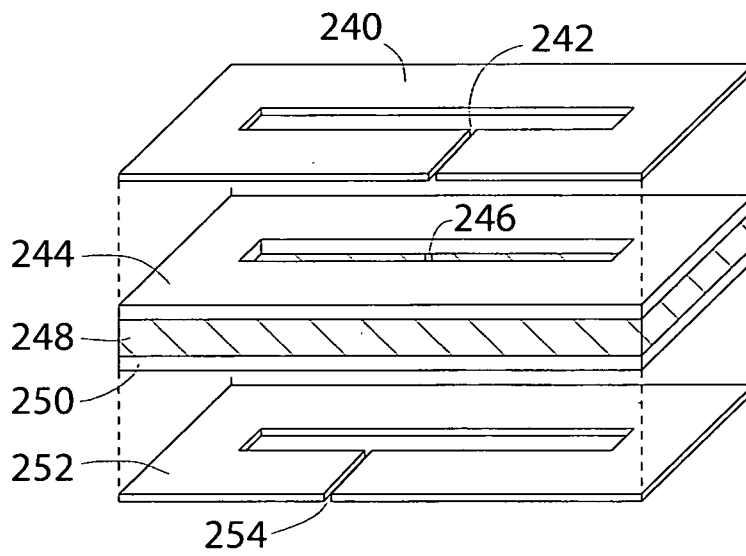


FIG. 20a

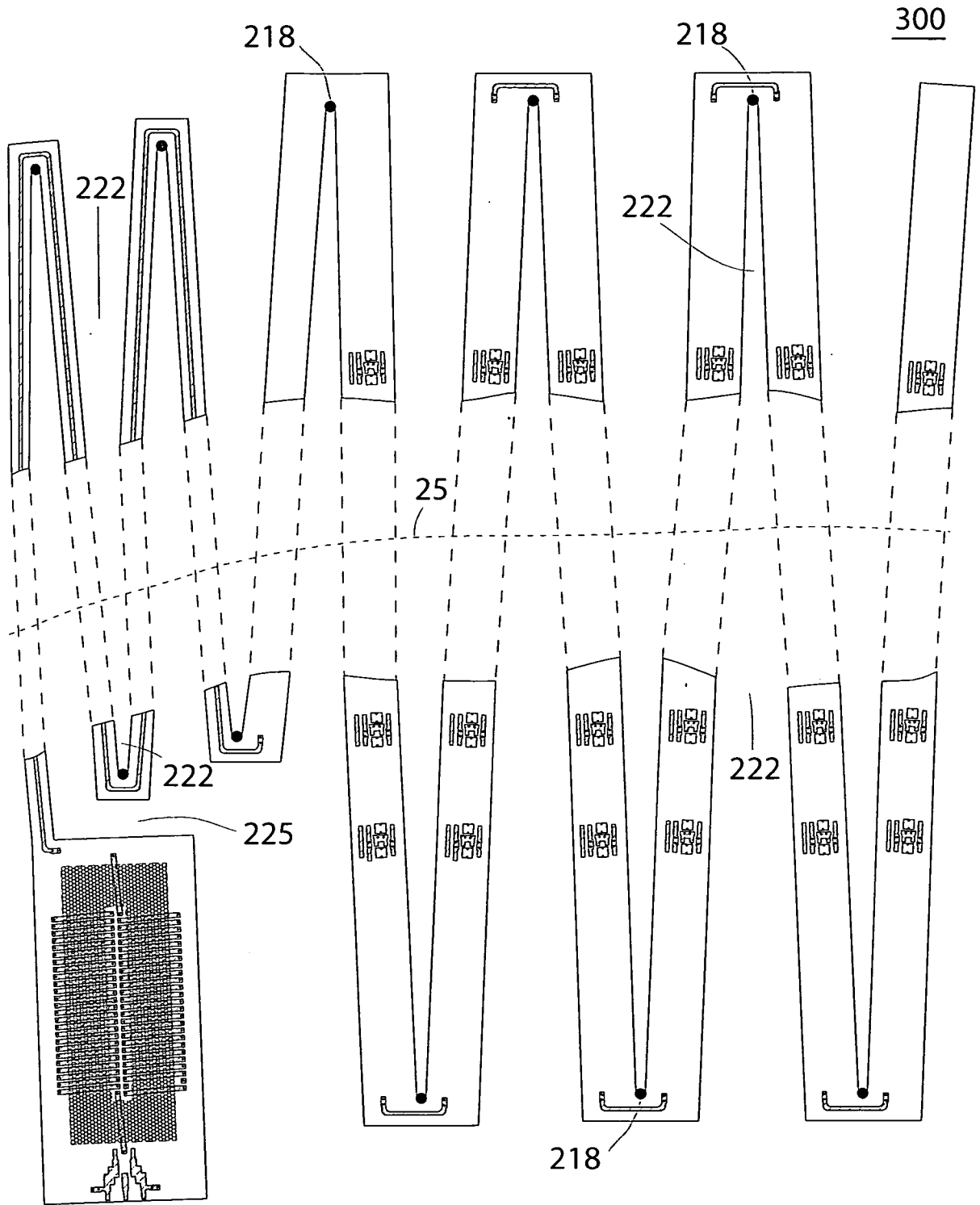


FIG. 21

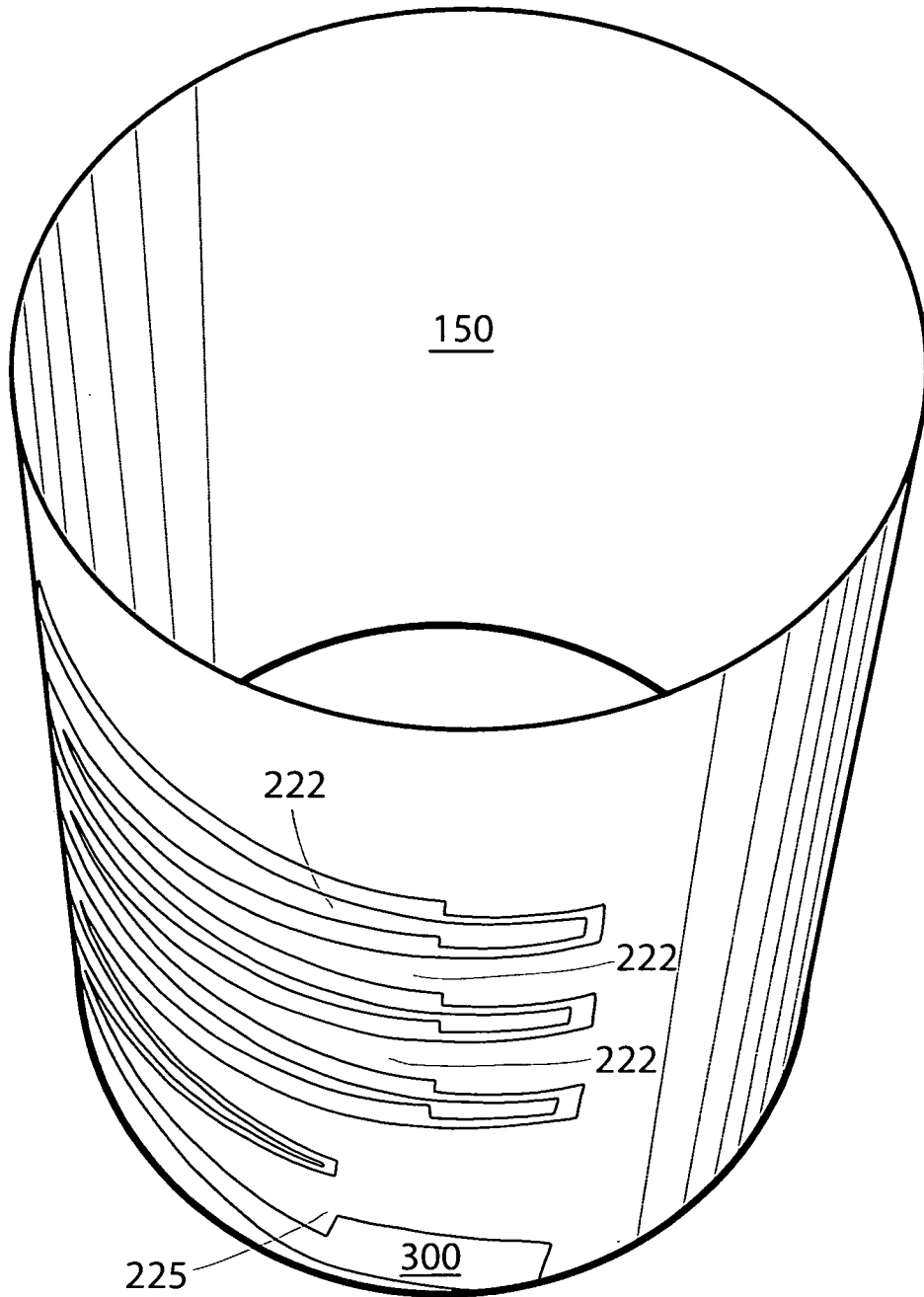


FIG. 22